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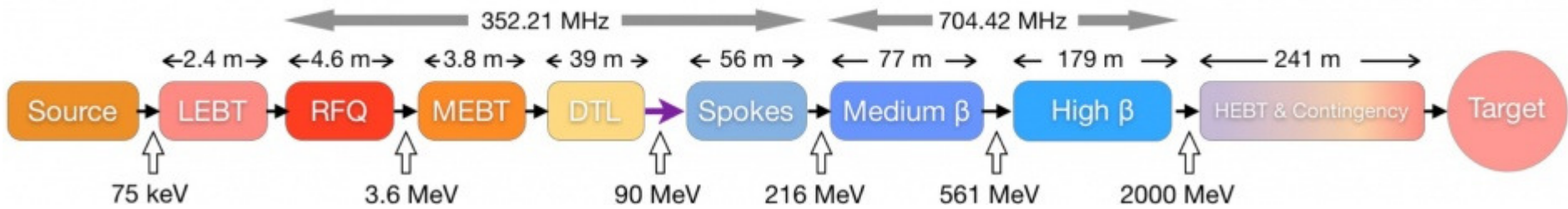


From microscopic to macroscopic dynamics of super-conducting accelerating cavities

Anirban Krishna Bhattacharyya

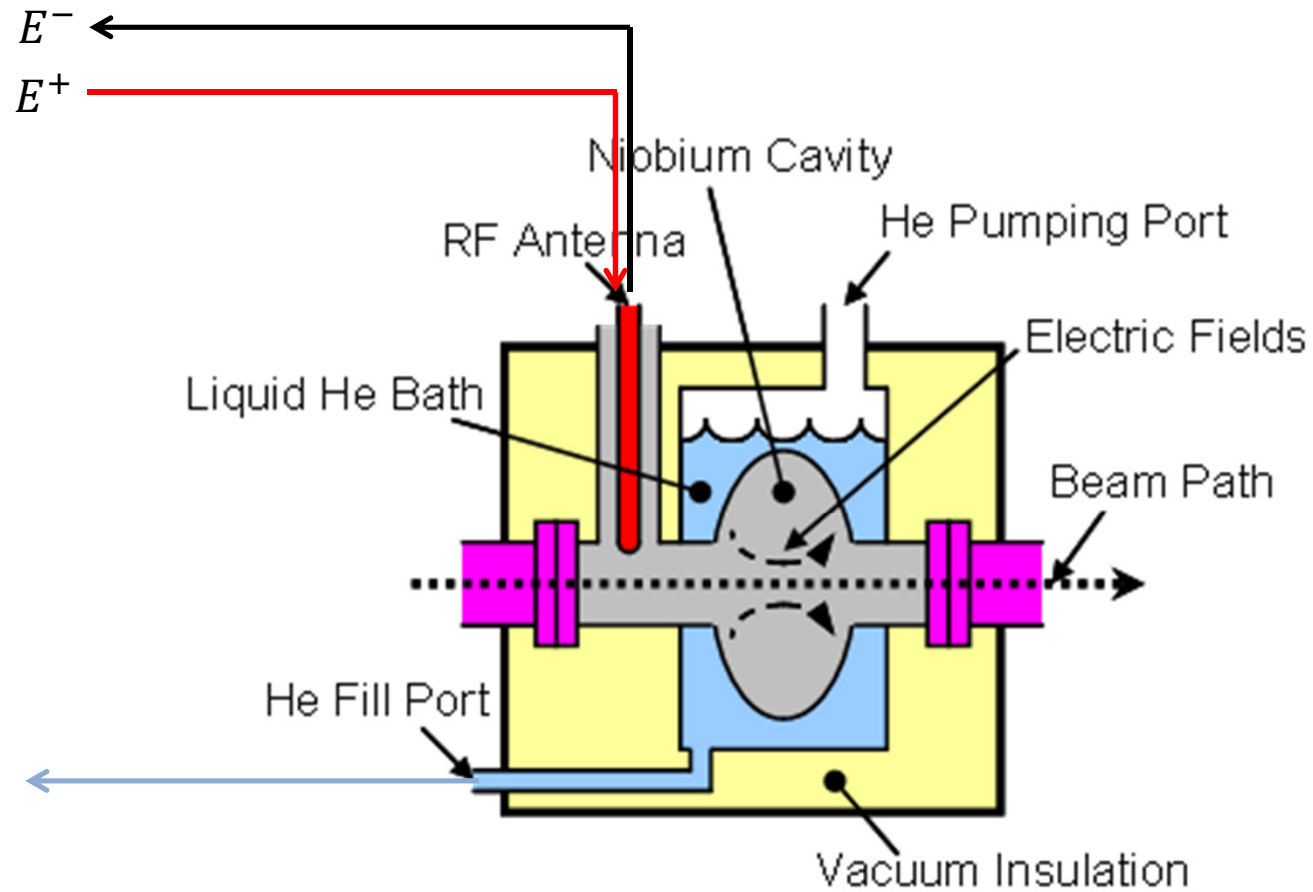


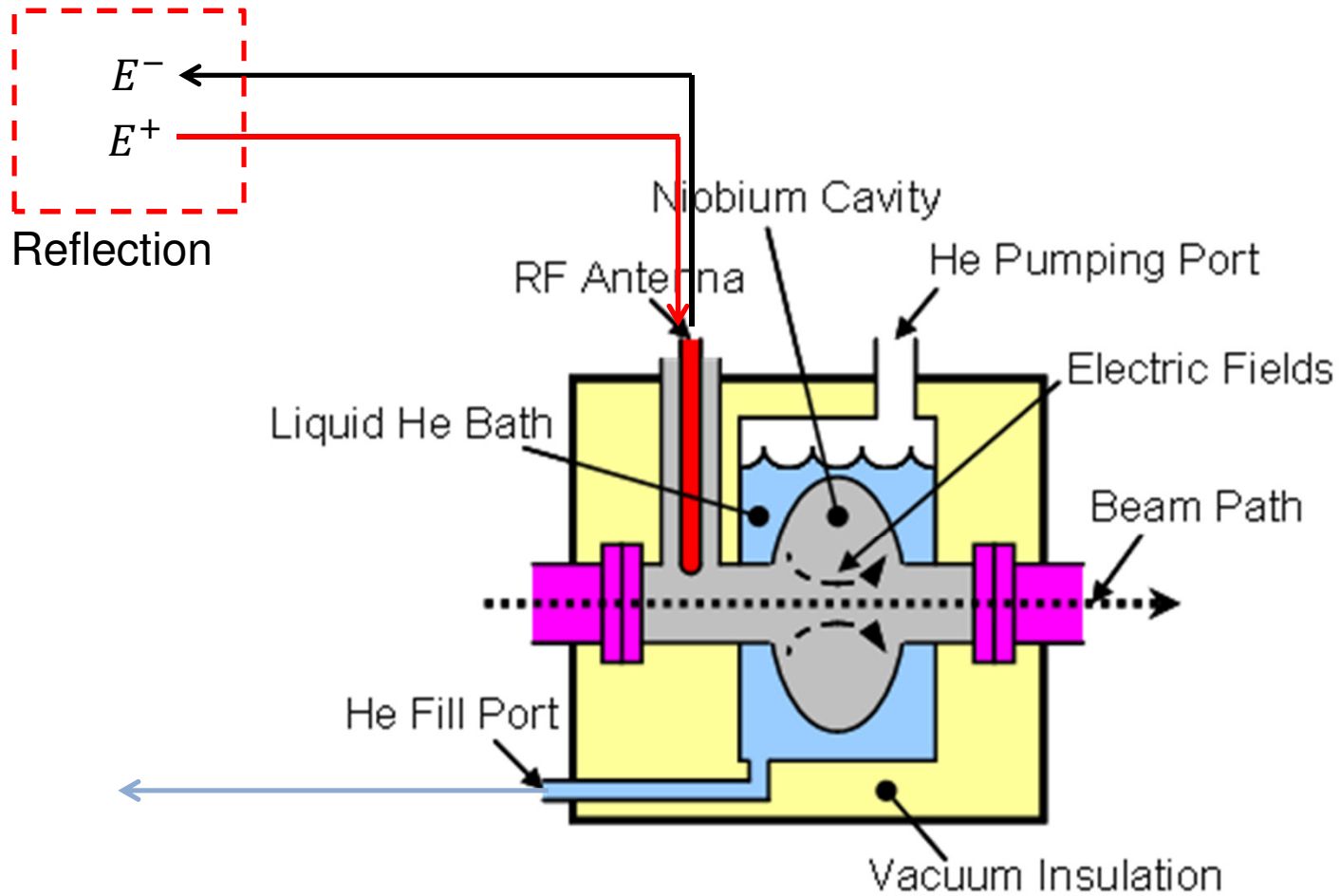
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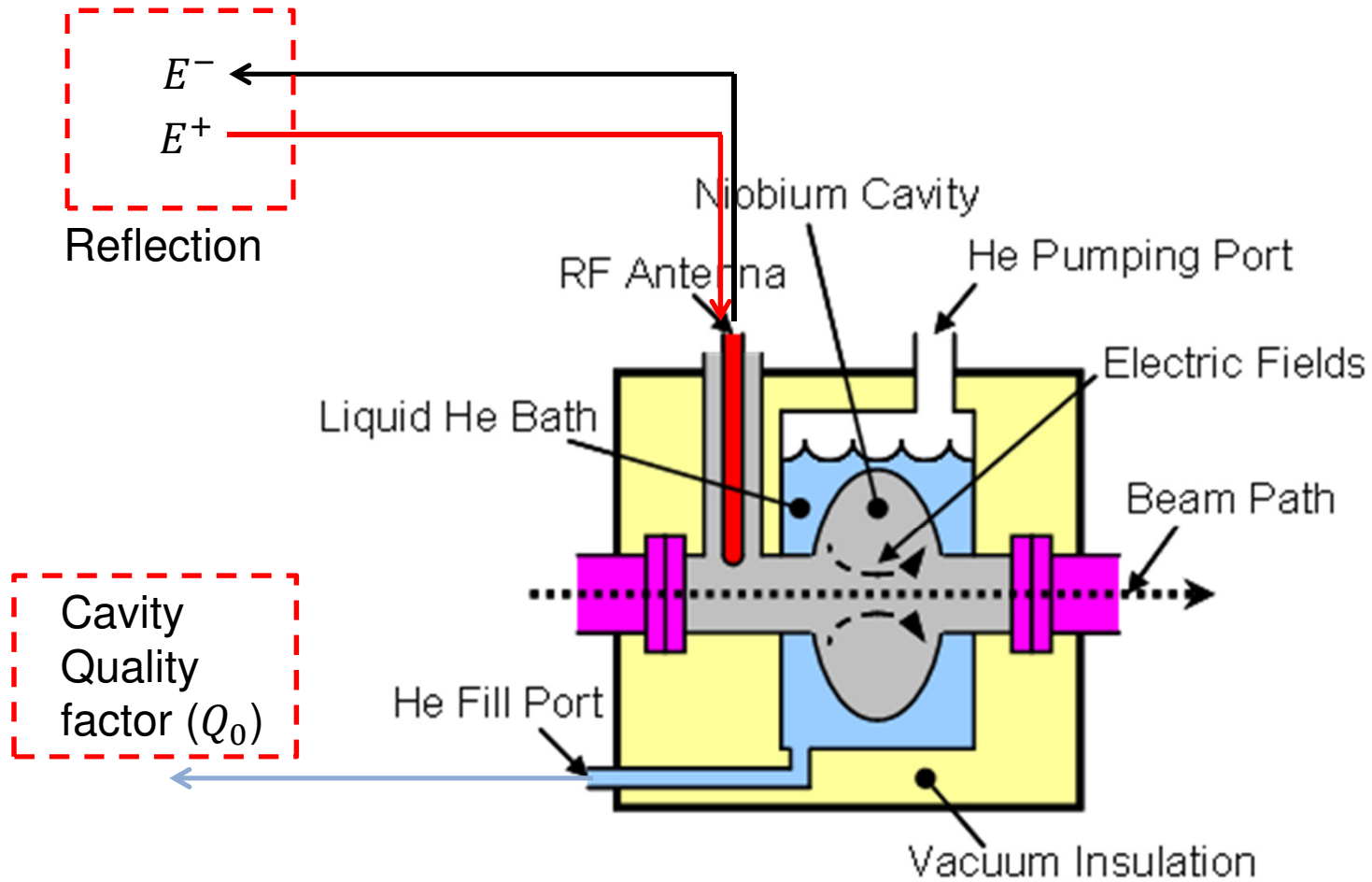


	Length (m)	Input Energy (MeV)	Frequency (MHz)	Geometric β	# of Sections	Temp (K)
RFQ	4.7	75×10^{-3}	352.2	--	1	≈ 300
DTL	19	3	352.2	--	3	≈ 300
Spoke	58	50	352.2	0.5	14 (2c)	≈ 2
Low Beta	108	188	704.4	0.70	16 (4c)	≈ 2
High Beta	196	606	704.4	0.90	15 (8c)	≈ 2
HEBT	100	2500	--	--	--	--

Courtesy Matts Lindroos (ESS)



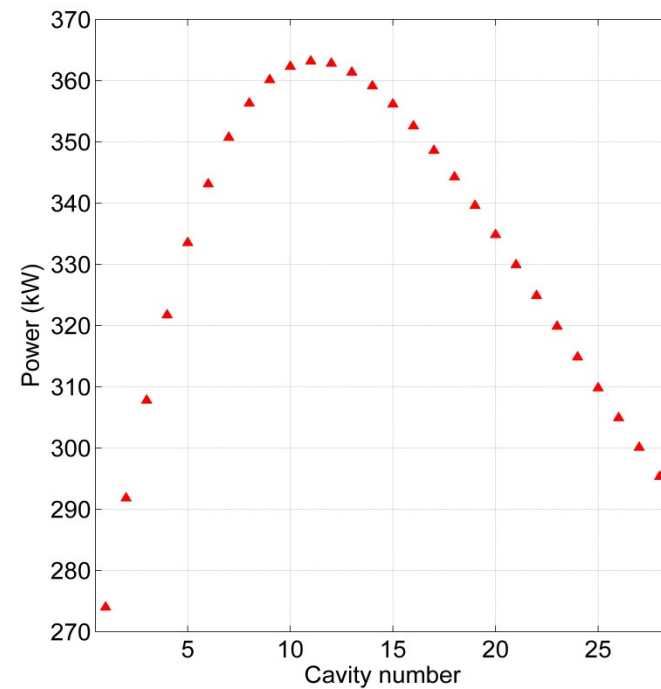
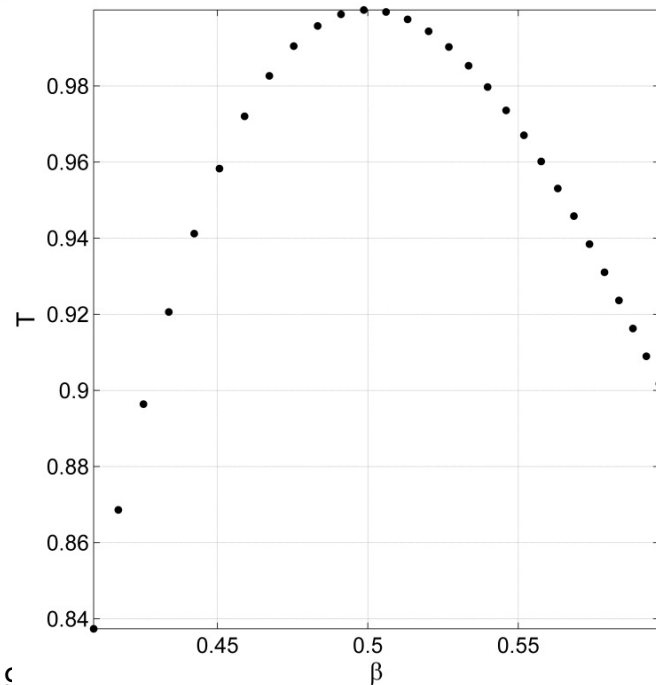




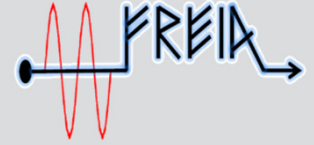
Cavity Parameters



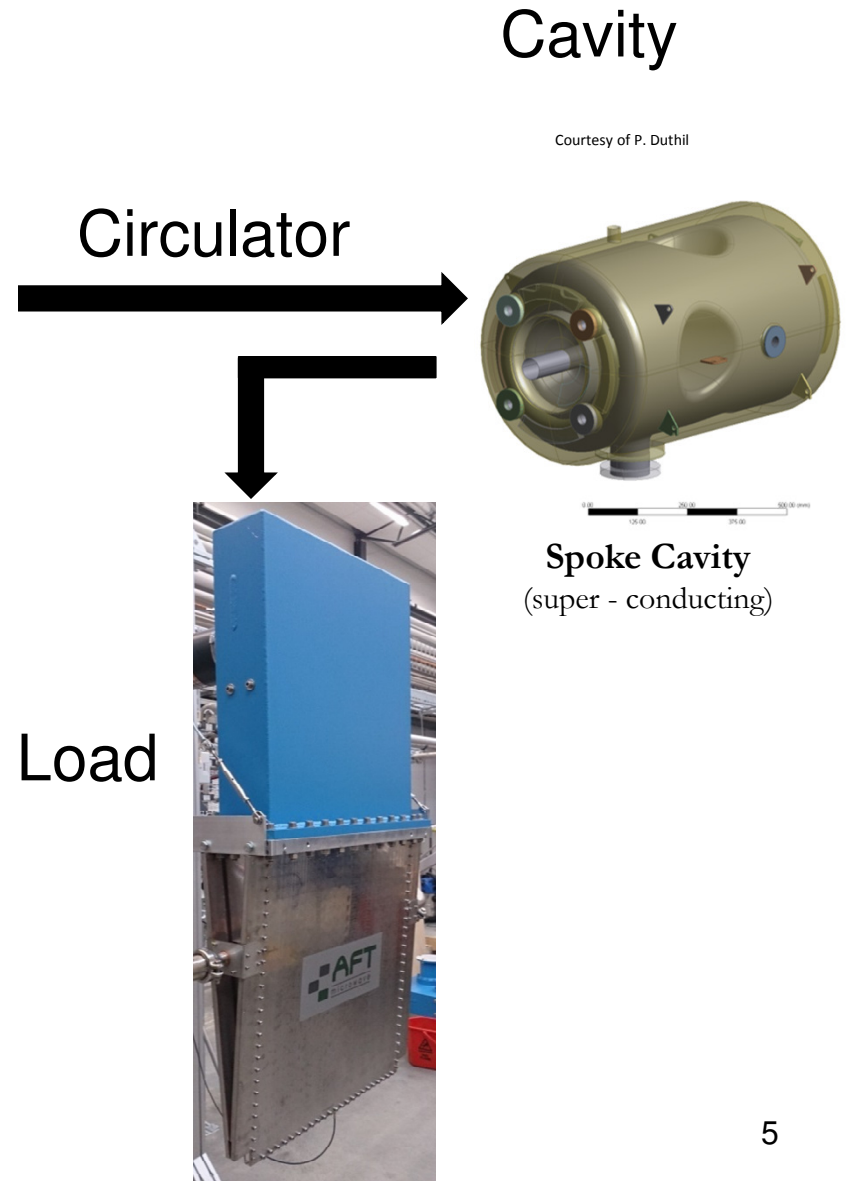
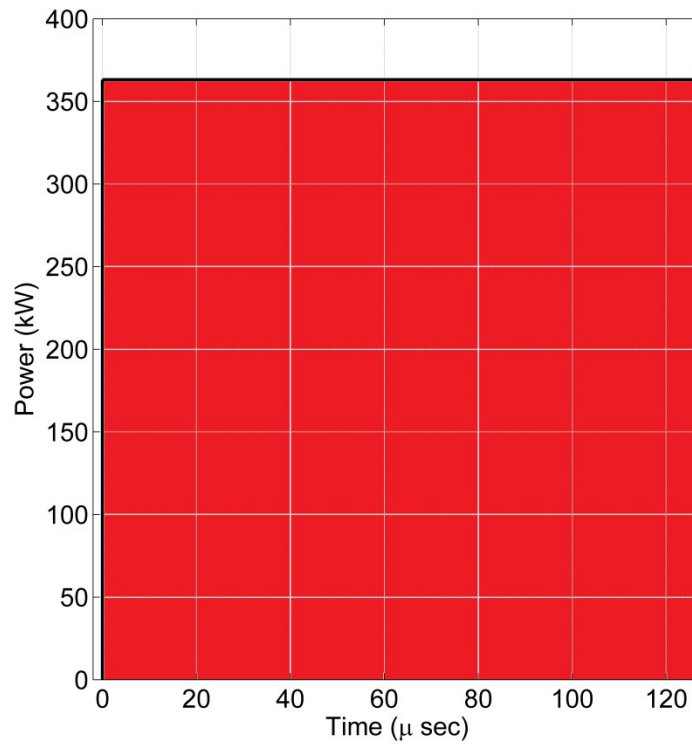
PARAMETER	SYMBOL	VALUE
Geometric beta	β	0.5
Accelerating gaps	n	3
Bare cavity Quality factor	Q_0	1.2×10^{10}
External Quality factor	Q_{ext}	1.76×10^5
Cavity shape constant	R/Q	213 Ω
DC beam current	$I_{b,DC}$	62.5 mA



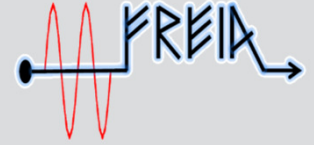
Step Charging



RF
Source



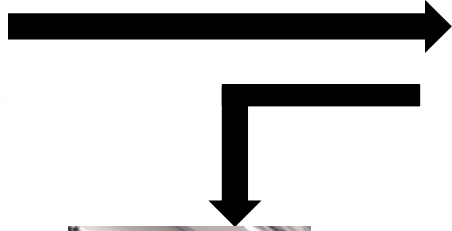
Step Charging



RF
Source

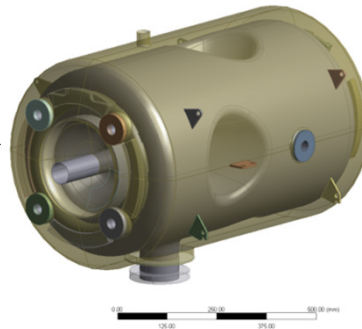


Circulator



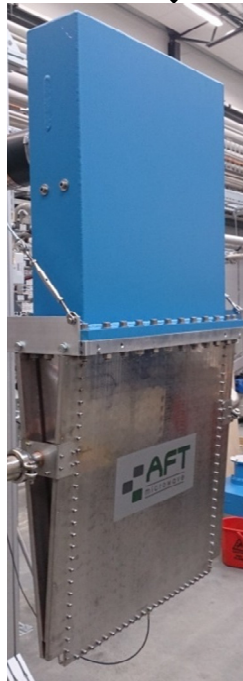
Cavity

Courtesy of P. Duthil

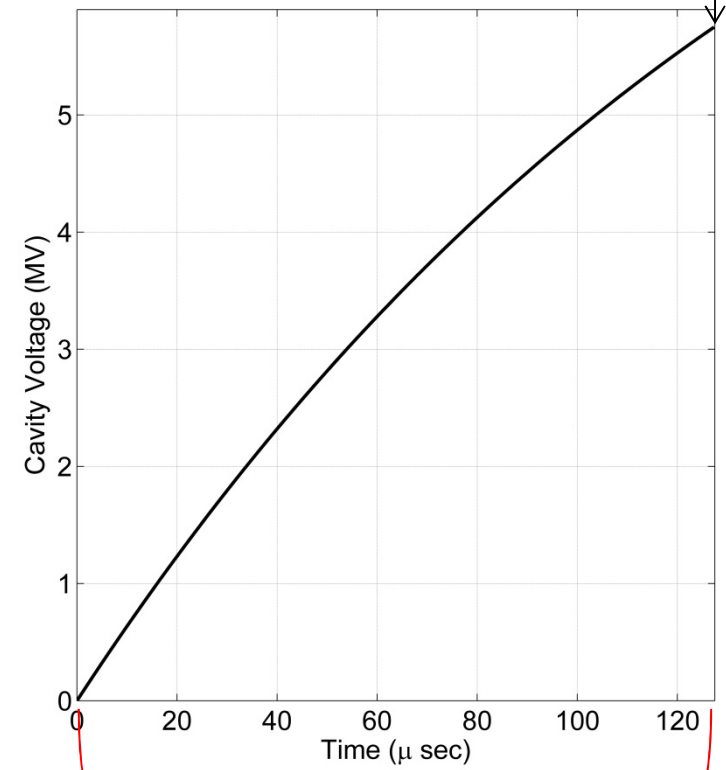


Spoke Cavity
(super - conducting)

Load



Beam injection t_i

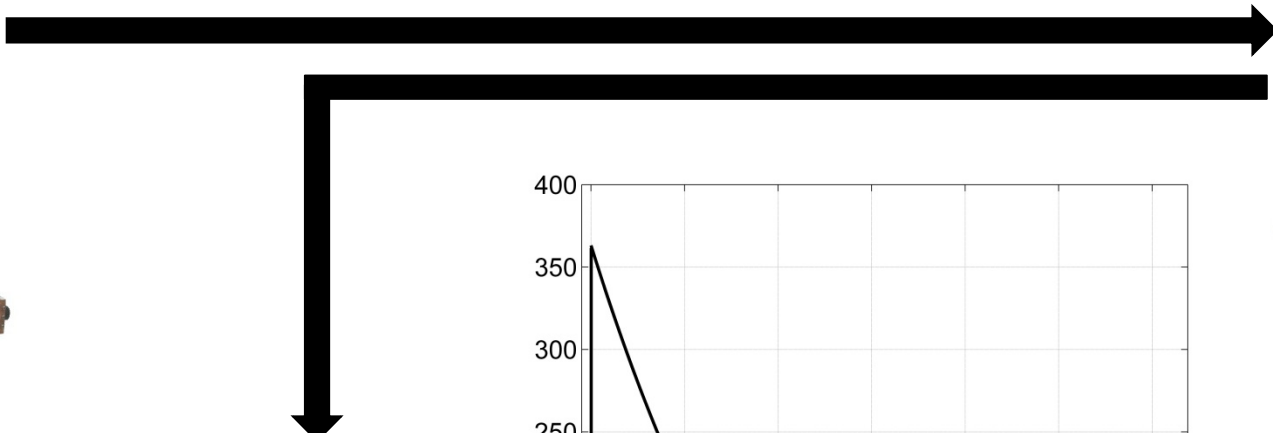


Charging time

RF
Source



Circulator



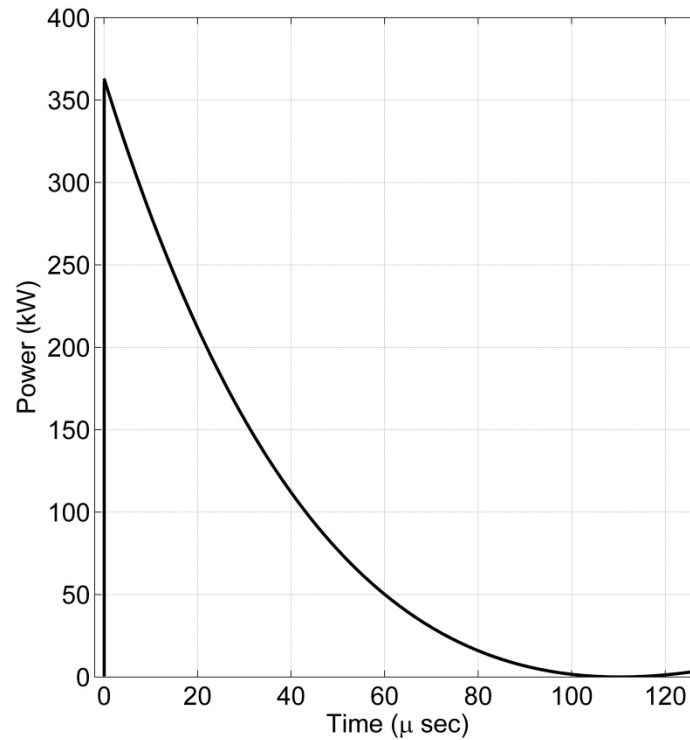
Cavity

Courtesy of P. Duthil

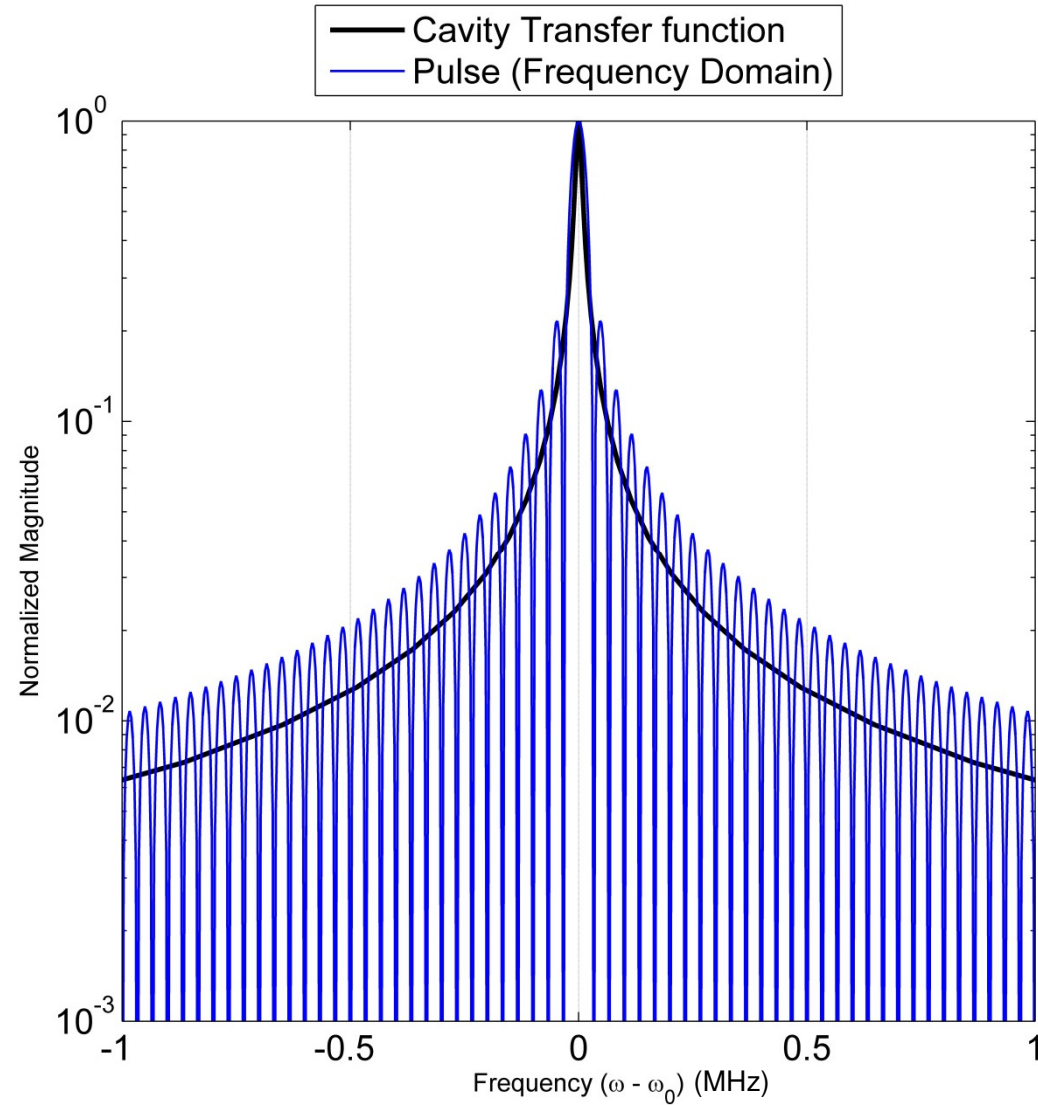


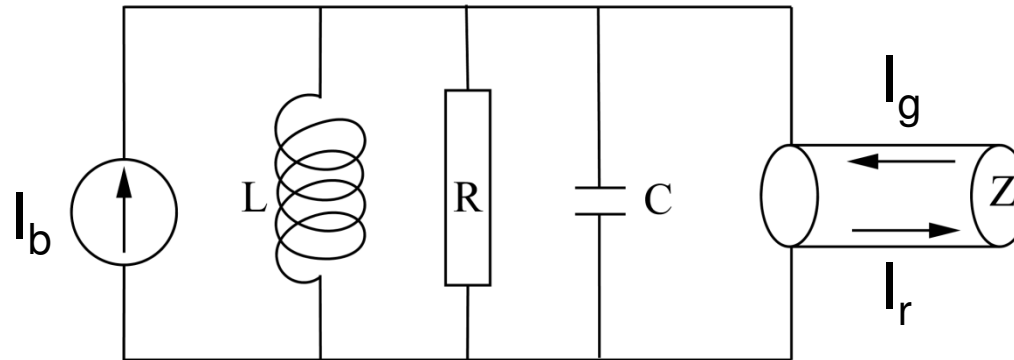
Spoke Cavity
(super - conducting)

Load



Step Charging (Frequency domain)





- Instantaneous cavity voltage ($V(t)$)

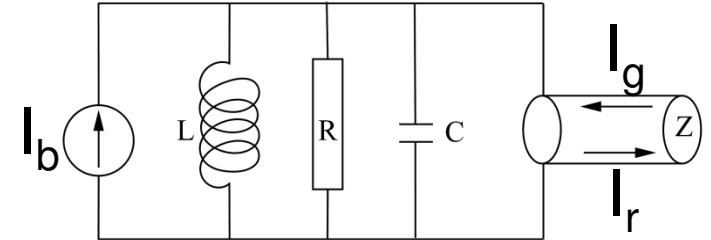
$$t_F \dot{V}(t) + \left(1 - i \frac{2\Delta\omega}{\omega} Q_L\right) V(t) = 2Z_L T I_g(t)$$

Filling time (Natural time scale) Loaded Quality factor Loaded cavity impedance Generator current

\downarrow
 V_c (Nominal cavity voltage)



- Instantaneous cavity voltage($V(t)$)



$$t_F \dot{V}(t) + \left(1 - i \frac{2\Delta\omega}{\omega} Q_L\right) V(t) = 2Z_L T I_g(t)$$

Filling time
(Natural time
scale)

Loaded
Quality
factor

Loaded
cavity
impedance

Generator
current

- Reflected current

$$I_r(t) = \frac{V(t)}{2(R/Q)T} \left(\frac{1}{Q_{ext}} - \frac{1}{Q_0} + 2i \frac{\Delta\omega}{\omega} \right) - \dot{V}(t) \frac{1}{\omega(R/Q)T}$$

External
Quality factor

Bare cavity
Quality factor

- Instantaneous cavity voltage

$$t_F \dot{V}(t) + \left(1 - i \frac{2\Delta\omega}{\omega} Q_L\right) V(t) = 2Z_L T I_g(t)$$

Filling time
Loaded Q
Loaded impedance
Generator current

- Reflected current

$$I_r(t) = \frac{V(t)}{2(R/Q)T} \left(\frac{1}{Q_{ext}} - \frac{1}{Q_0} + 2i \frac{\Delta\omega}{\omega} \right) - \dot{V}(t) \frac{1}{\omega(R/Q)T}$$

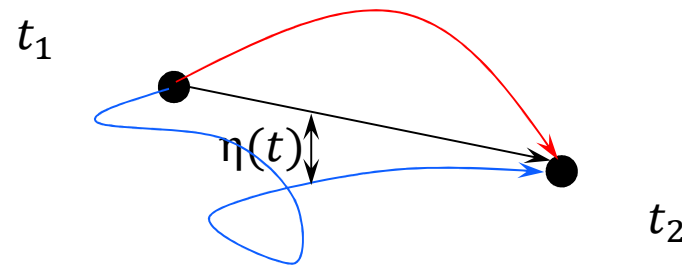
External Q
Bare cavity Q

- Reflected energy ($\Delta\omega = 0$)

$$\frac{1}{2} \frac{Q_{ext}}{(R/Q)T^2} \int_0^{\hat{t}_i} \left| \frac{V(\tilde{t})}{2} \left(\frac{1}{Q_{ext}} - \frac{1}{Q_0} \right) - \frac{dV(\tilde{t})}{d\tilde{t}} \frac{1}{\omega} \right|^2 d\tilde{t}$$

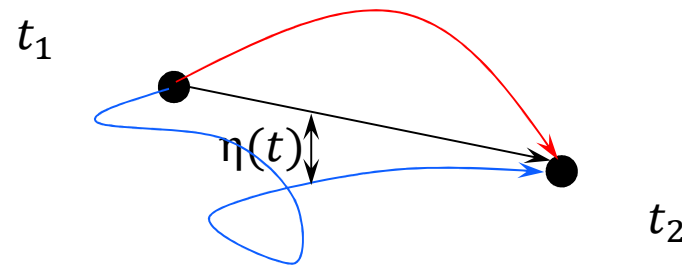
$$V(t) = V_c \text{ at } t = \hat{t}_i$$

Minimum Action: Example from classical mechanics



$$S = \int_{t_1}^{t_2} (K.E. - P.E.) dt = \int_{t_1}^{t_2} L dt = \int_{t_1}^{t_2} \left[\frac{1}{2} m \left(\frac{dx}{dt} \right)^2 - V(x) \right] dt$$

Minimum Action: Example from classical mechanics



$$S = \int_{t_1}^{t_2} (K.E. - P.E.) dt = \int_{t_1}^{t_2} L dt = \int_{t_1}^{t_2} \left[\frac{1}{2} m \left(\frac{dx}{dt} \right)^2 - V(x) \right] dt$$

$$L(V, \dot{V}, t) = \frac{1}{2} \frac{Q_{ext}}{(R/Q)T^2} \left| \frac{V(\tilde{t})}{2} \left(\frac{1}{Q_{ext}} - \frac{1}{Q_0} \right) - \frac{dV(\tilde{t})}{d\tilde{t}} \frac{1}{\omega} \right|^2 d\tilde{t}$$

$$\frac{\partial L}{\partial V} - \frac{d}{dt} \frac{\partial L}{\partial \dot{V}} = 0$$

- The concept of minimum action,

Find optimal $V(t)$ and $\dot{V}(t)$ such that $L(V, \dot{V}, t)$ is minimum.

$$\frac{\partial L}{\partial V} - \frac{d}{dt} \frac{\partial L}{\partial \dot{V}} = 0$$



Optimal charging profile

$$V^o(\tau) = V_c \frac{\sinh(\tau)}{\sinh(\hat{\tau}_i)},$$

$$I_g^o(\tau) = \frac{V_c}{2TZ_L} \frac{\exp \tau}{\sinh(\hat{\tau}_i)}$$

$$\tau = \frac{t}{t_F}, \quad \hat{\tau}_i = \frac{\hat{t}_i}{t_F}$$

- The concept of minimum action,

$$\frac{\partial L}{\partial V} - \frac{d}{dt} \frac{\partial L}{\partial \dot{V}} = 0$$

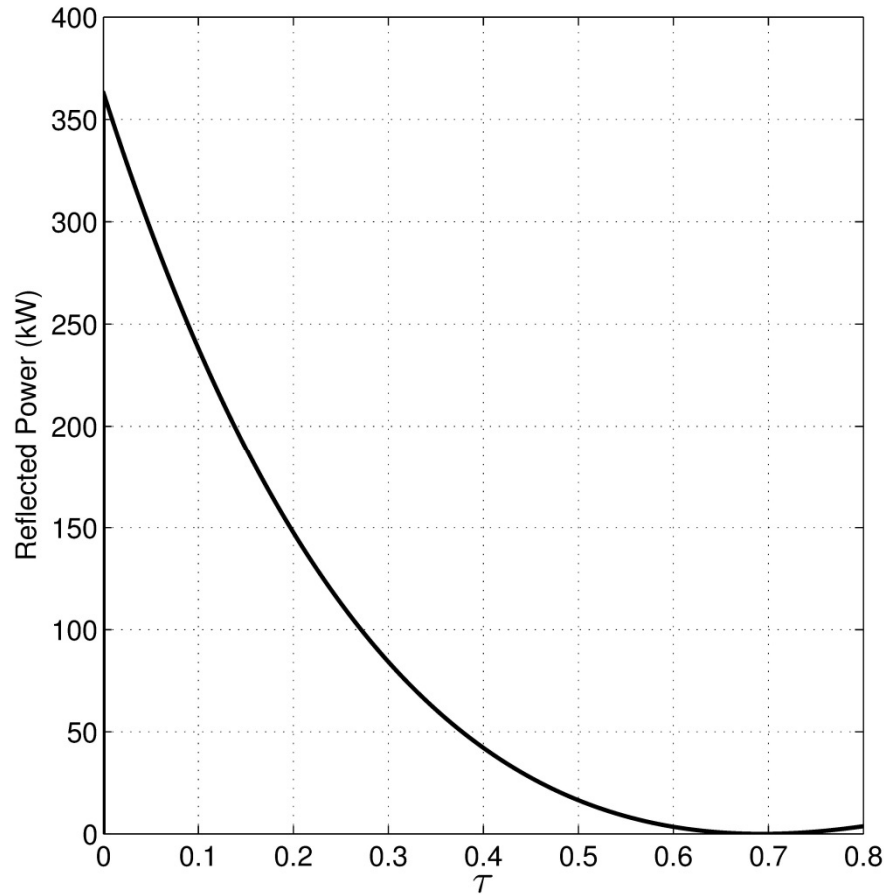


Optimal charging profile

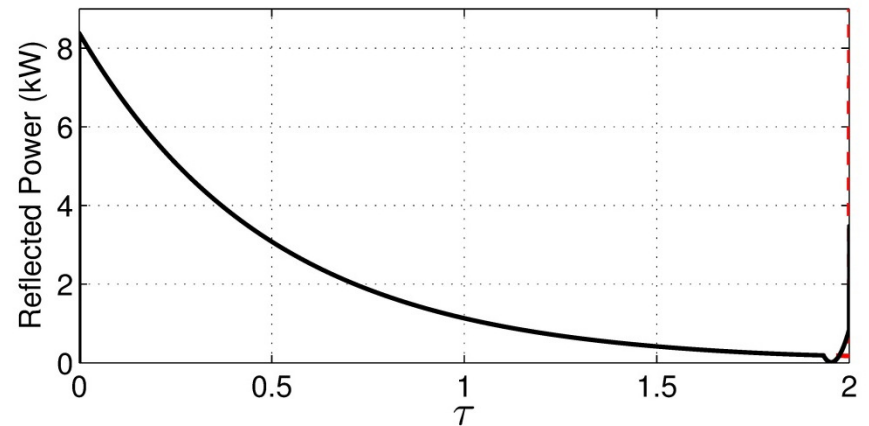
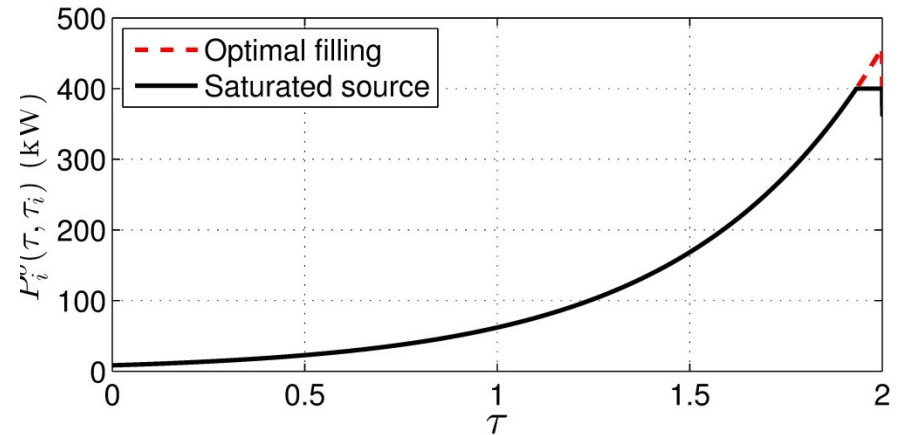
$$V^o(\tau) = V_c \frac{\sinh(\tau)}{\sinh(\hat{\tau}_i)},$$

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$$\tau = \frac{t}{t_F}, \quad \hat{\tau}_i = \frac{\hat{t}_i}{t_F} \leftarrow \text{Free parameter}$$



Step filling

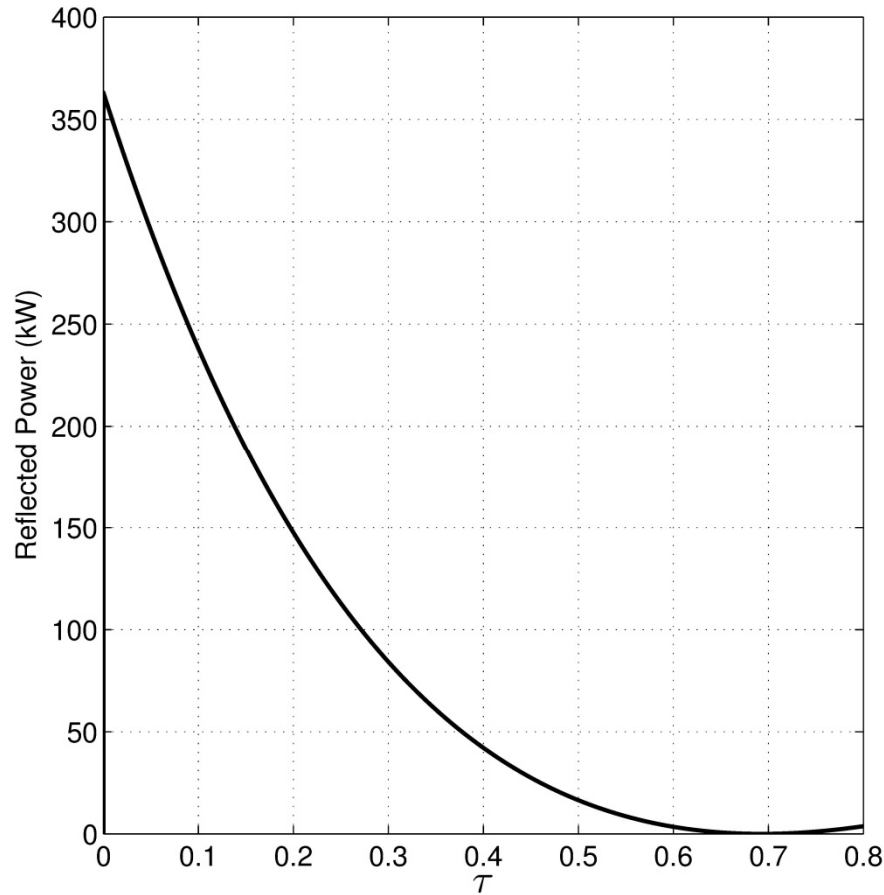


Optimal filling

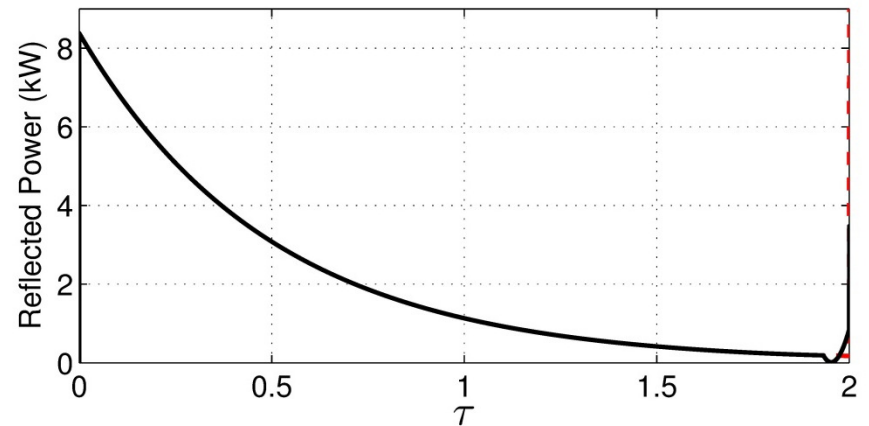
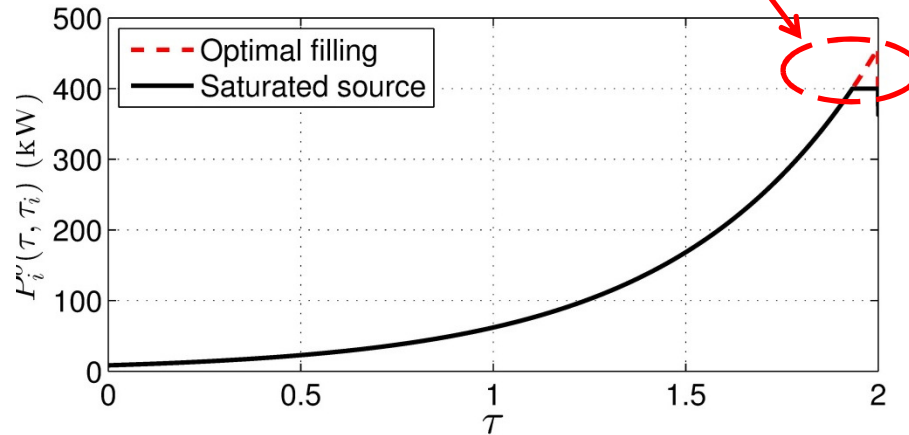
Effect of Optimal filling



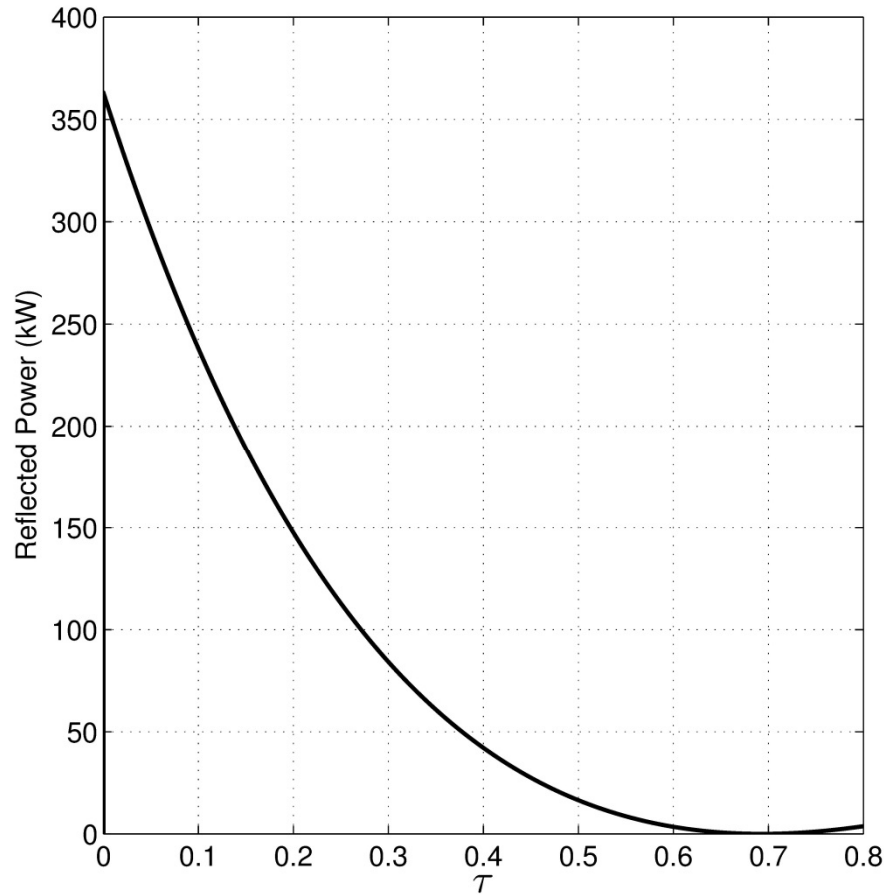
No free lunch!!!



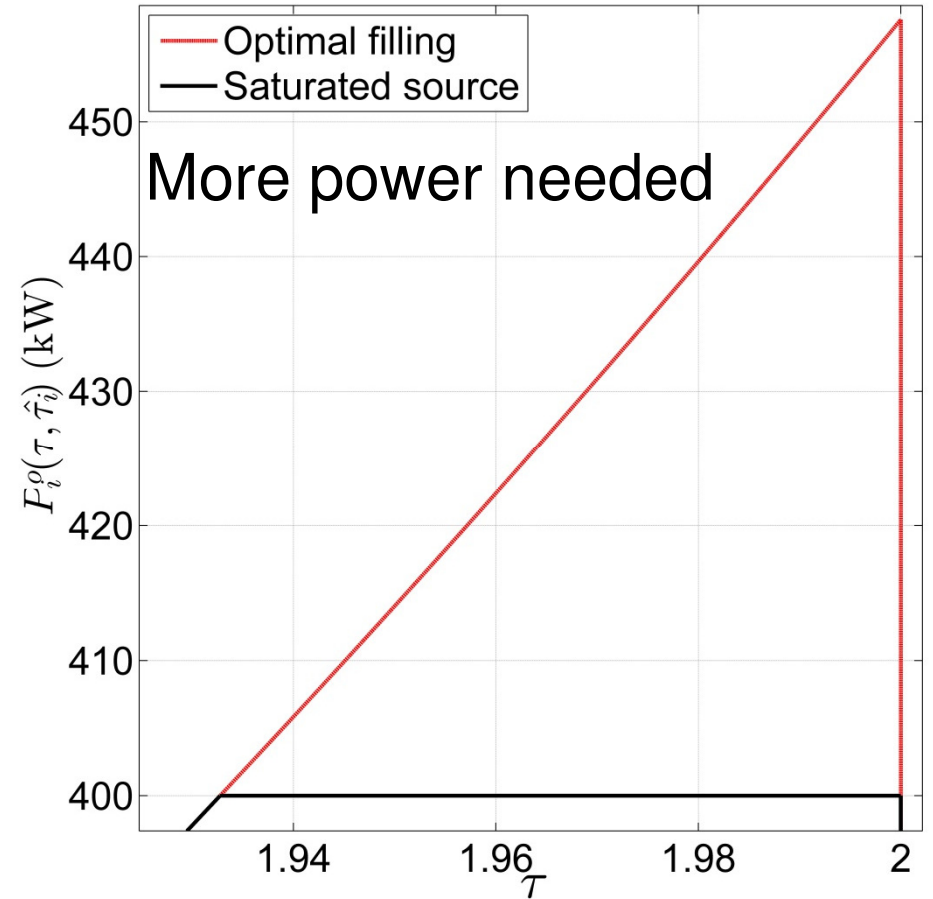
Step filling



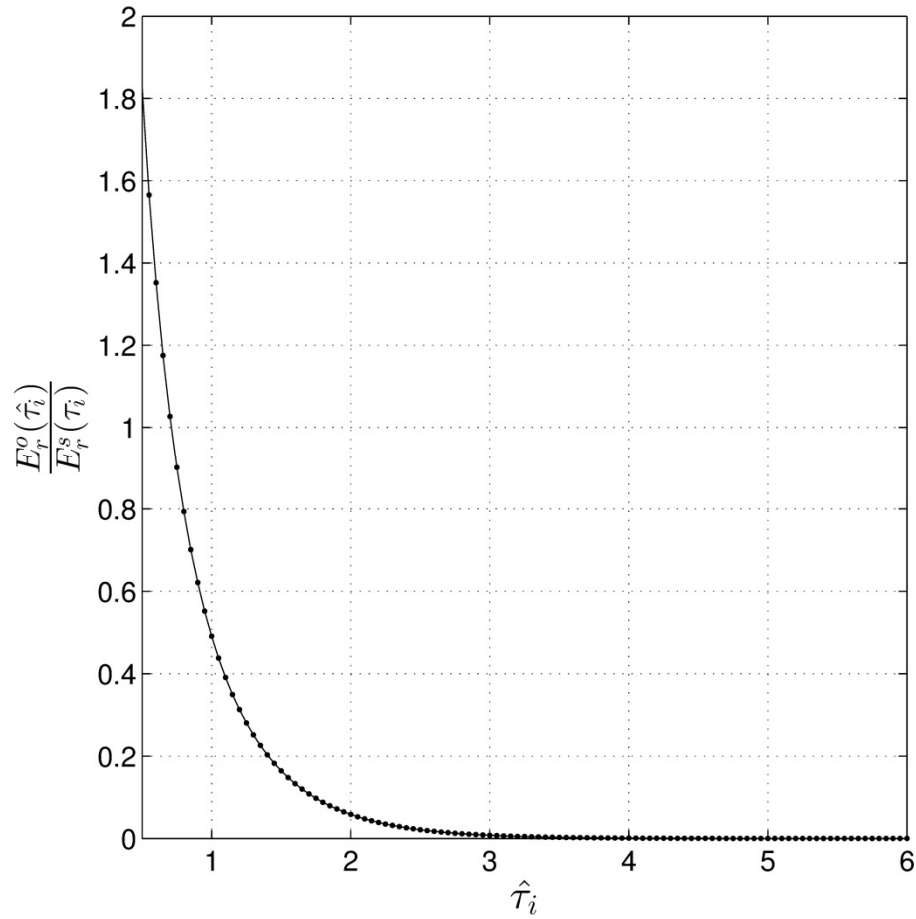
Optimal filling



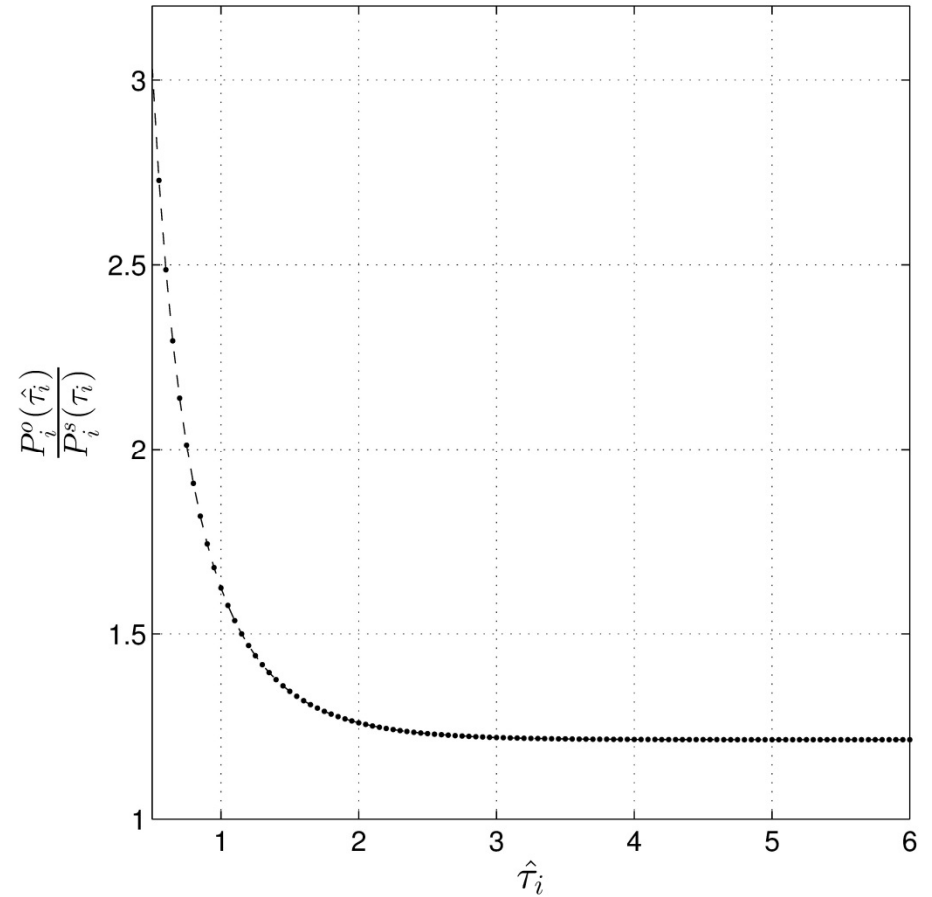
Step filling



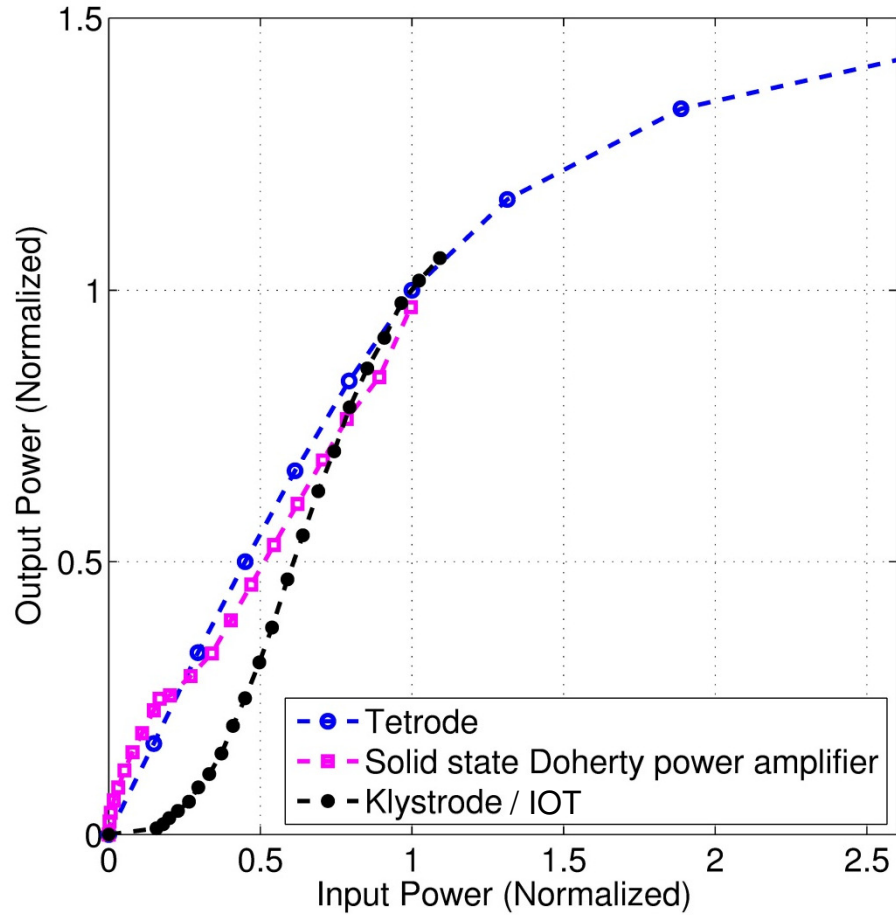
Optimal filling



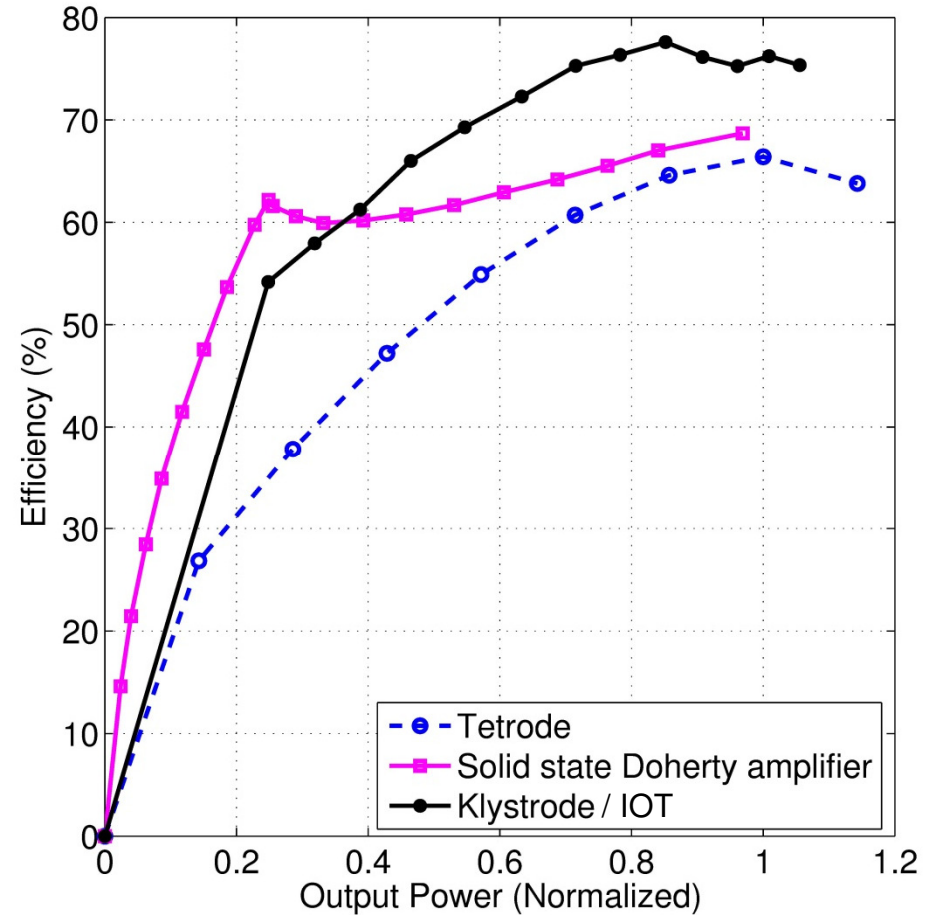
Relative reflected energy



Peak generator power



Gain characteristics



Efficiency characteristics



W. Doherty, A new high efficiency power amplifier for modulated waves, Radio Engineers, Proceedings of the Institute of 24 (9) (1936) 1163–1182. doi:10.1109/JRPROC.1936.228468.

B. Kim, J. Kim, I. Kim, J. Cha, The doherty power amplifier, Microwave Magazine, IEEE 7 (5) (2006) 42–50. doi:10.1109/MW-M.2006.247914.

R. Pengelly, N-way rf power amplifier with increased backoff power and power added efficiency, wO Patent App. PCT/US2003/002,365 (Aug. 7 2003).
URL <http://www.google.com/patents/WO2003065573A1?cl=en>

P. Colantonio, F. Giannini, R. Giofr, L. Piazzon, The doherty power amplifier, INTERNATIONAL JOURNAL OF MICROWAVE AND OPTICAL TECHNOLOGY 5 (6) (2010) 419–430.

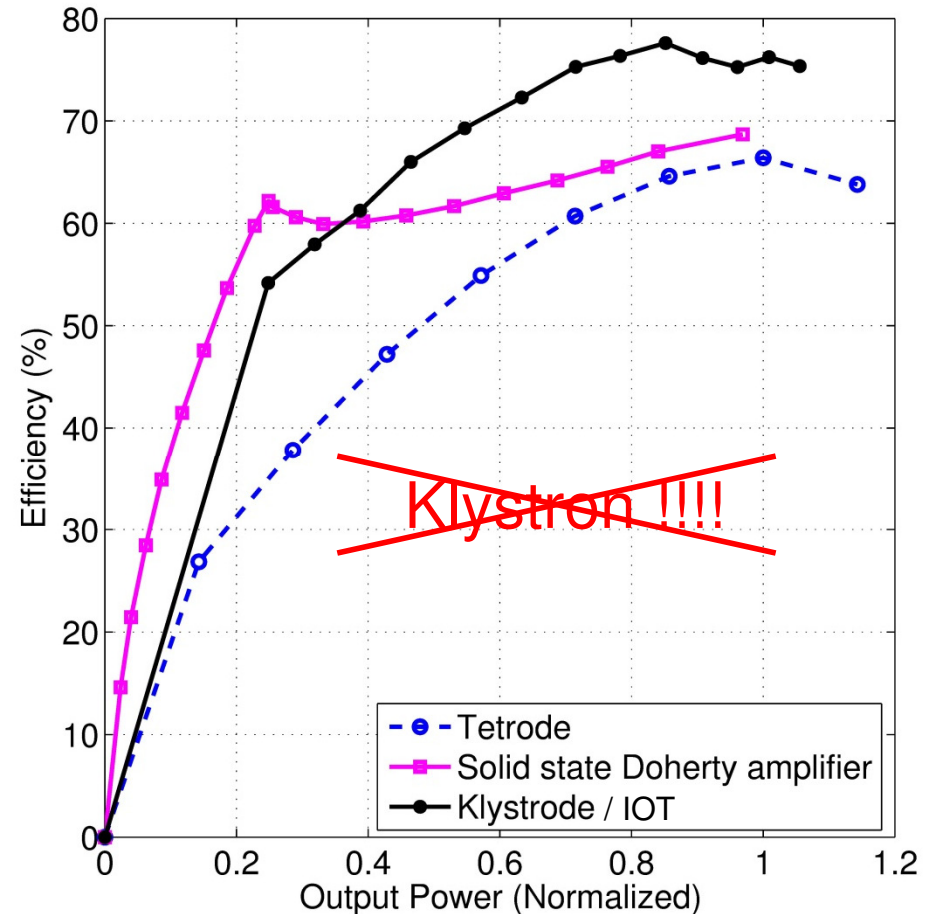
G. Ahn, M. su Kim, H. chul Park, S. chan Jung, J. ho Van, H. Cho, S. wook Kwon, J.-H. Jeong, K. hoon Lim, J. Y. Kim, S. C. Song, C.-S. Park, Y. Yang, Design of a high-efficiency and high-power inverted doherty amplifier, Microwave Theory and Techniques, IEEE Transactions on 55 (6) (2007) 1105–1111. doi:10.1109/TMTT.2007.896807.

NXP Semiconductors, AN10967 BLF578 demo for 352 MHz 1kW CW power, 2nd Edition, application note (November 2012).

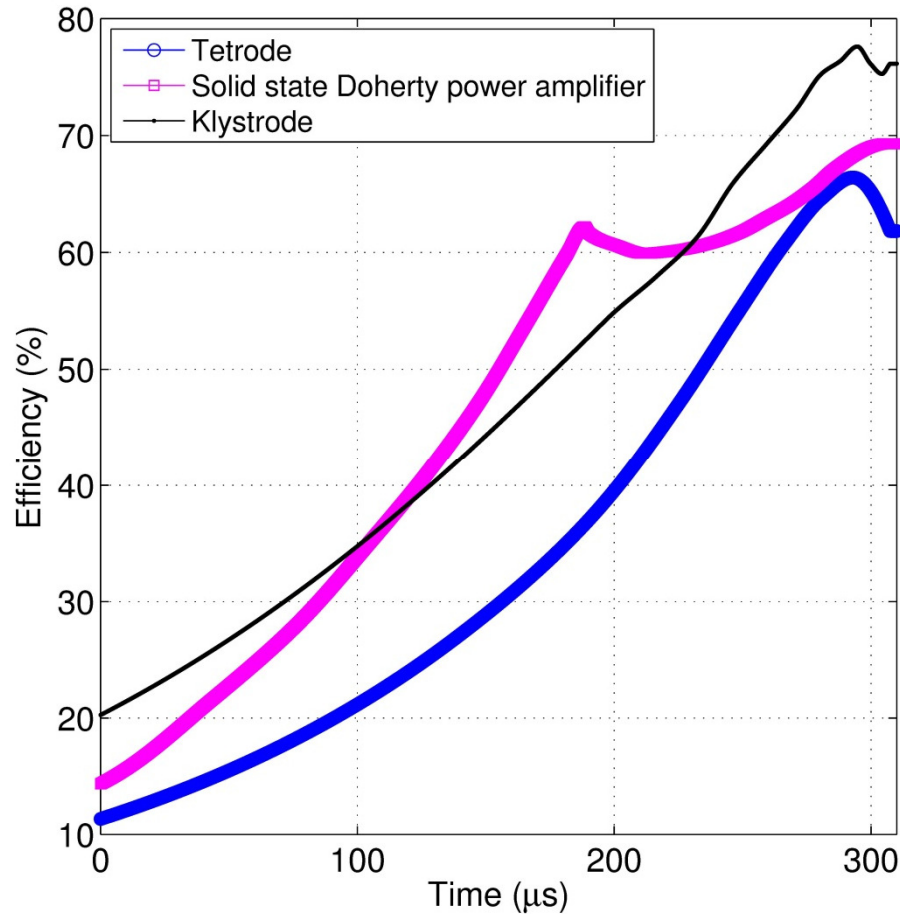
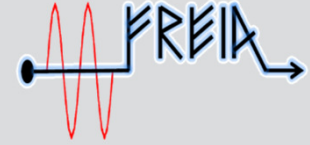
D. Rees, D. Keffeler, W. Roybal, P. Tallerico, Characterization of a Klystrode as a RF Source for High-Average-Power Accelerators, Conf.Proc. C950501 (1995) 1521.

E. Montesinos, Tetrode power amplifiers, in: TIARA Workshop on RF Power Generation for Accelerators, Uppsala University, A`ngstr`om Laboratory, 2013.

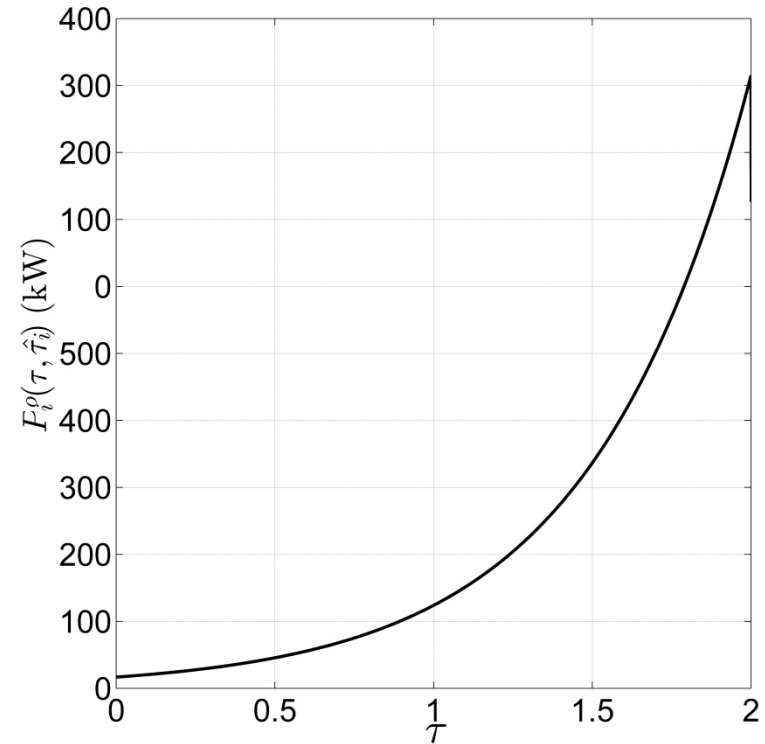
N. Pupeter, Significant increase of efficiency of solid state amplifiers due to improved ac/dc conversion and adaption of p1 point to actual operating power, in: EnEfficient RF Sources, Cockcroft Institute, 2014.



Efficiency characteristics



Source efficiency during filling

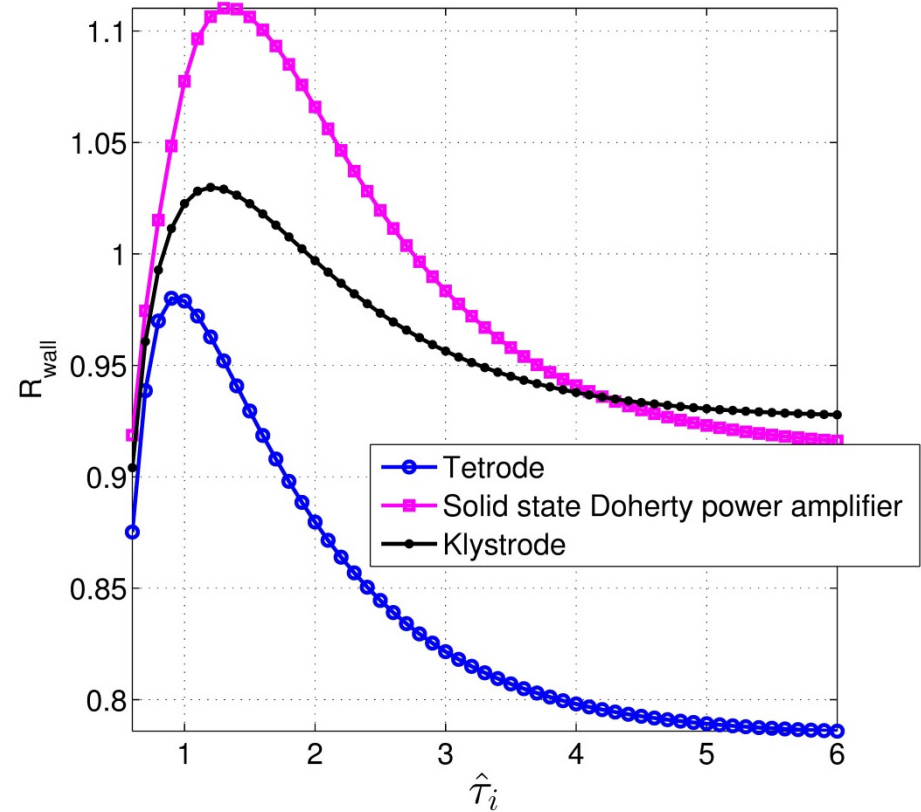
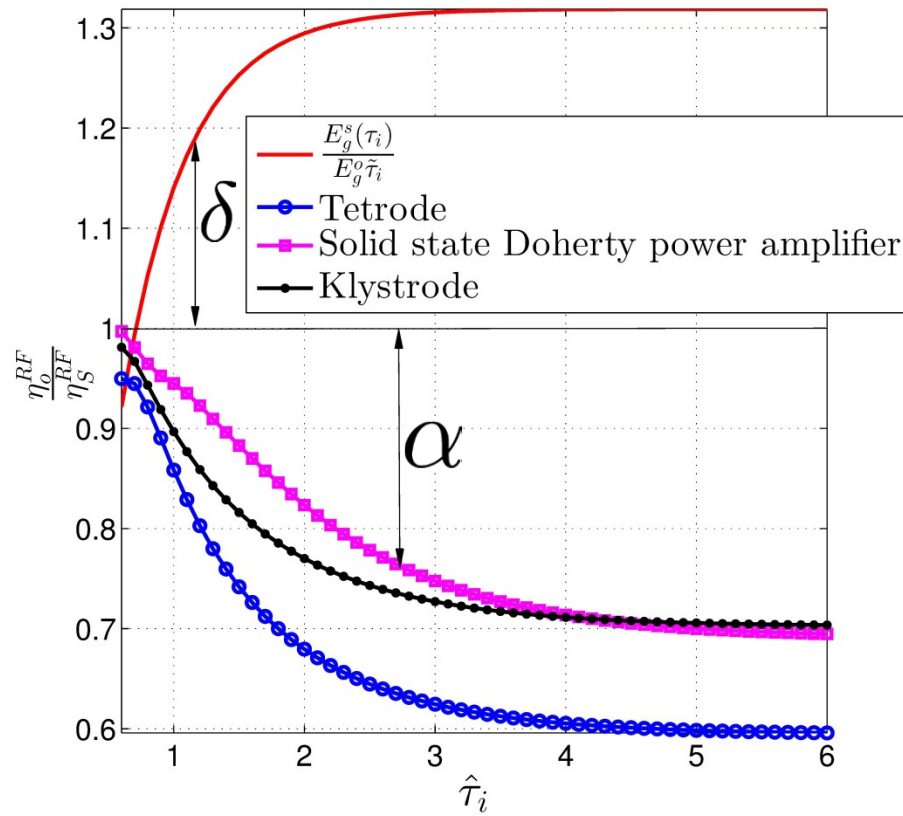


$$\hat{\tau}_i = 2$$

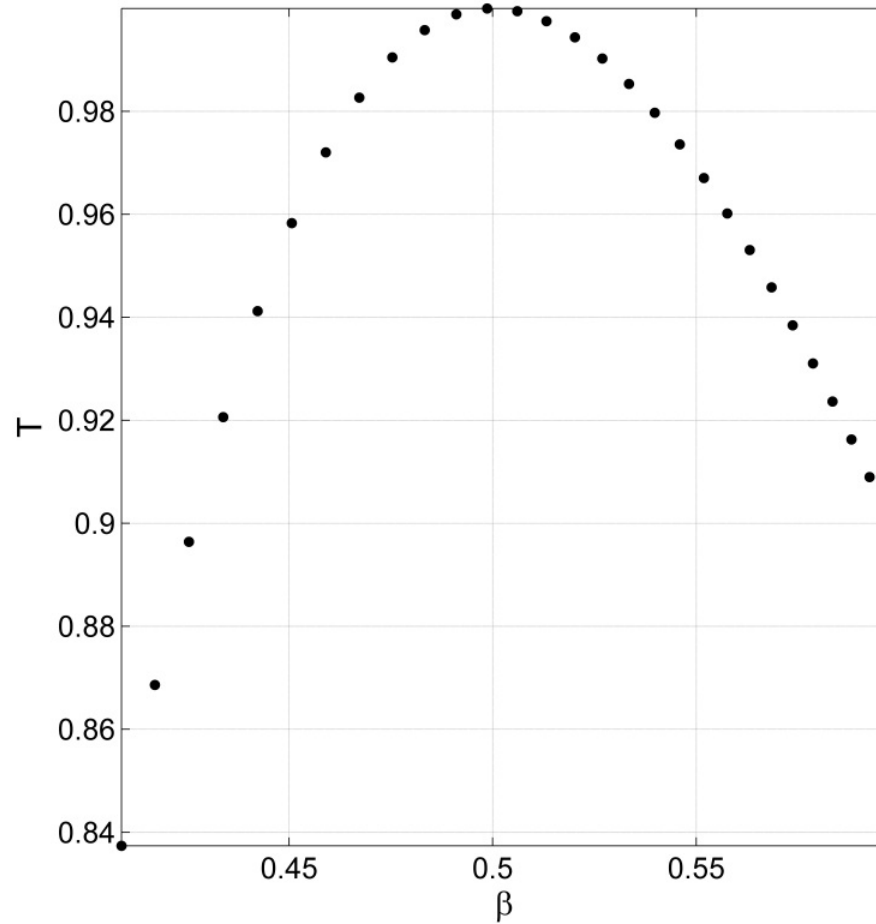
$$R_{wall} \approx 1 + \delta - \alpha$$

RF
Gain

Source
loss

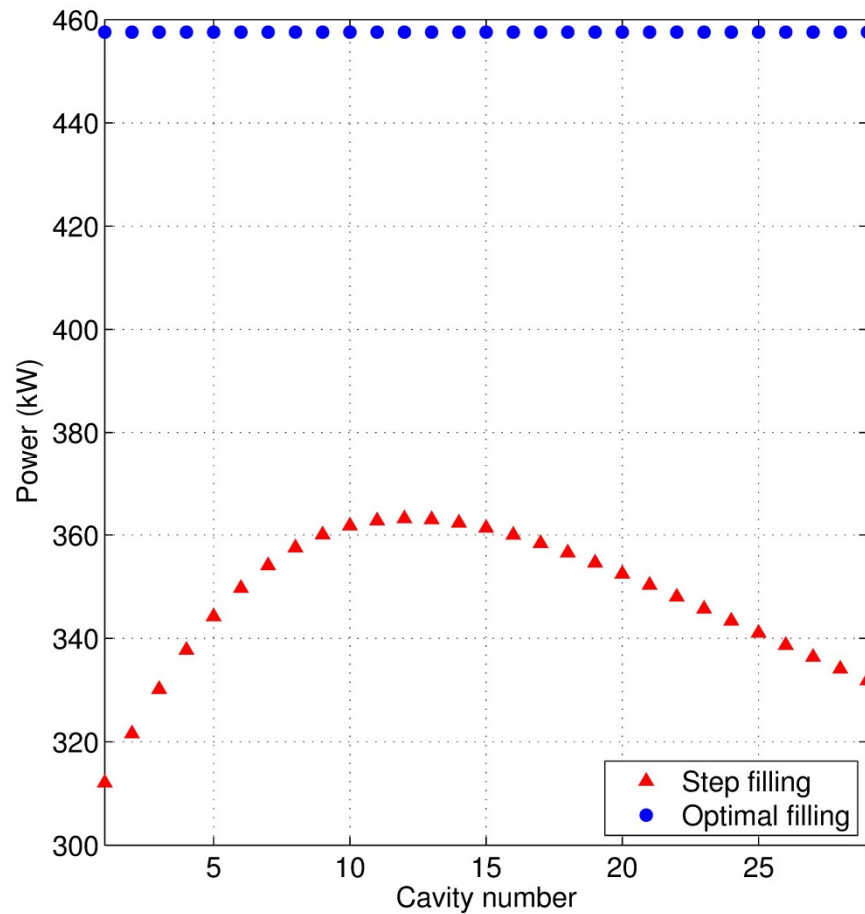


Tetrodes can be run in Doherty architecture

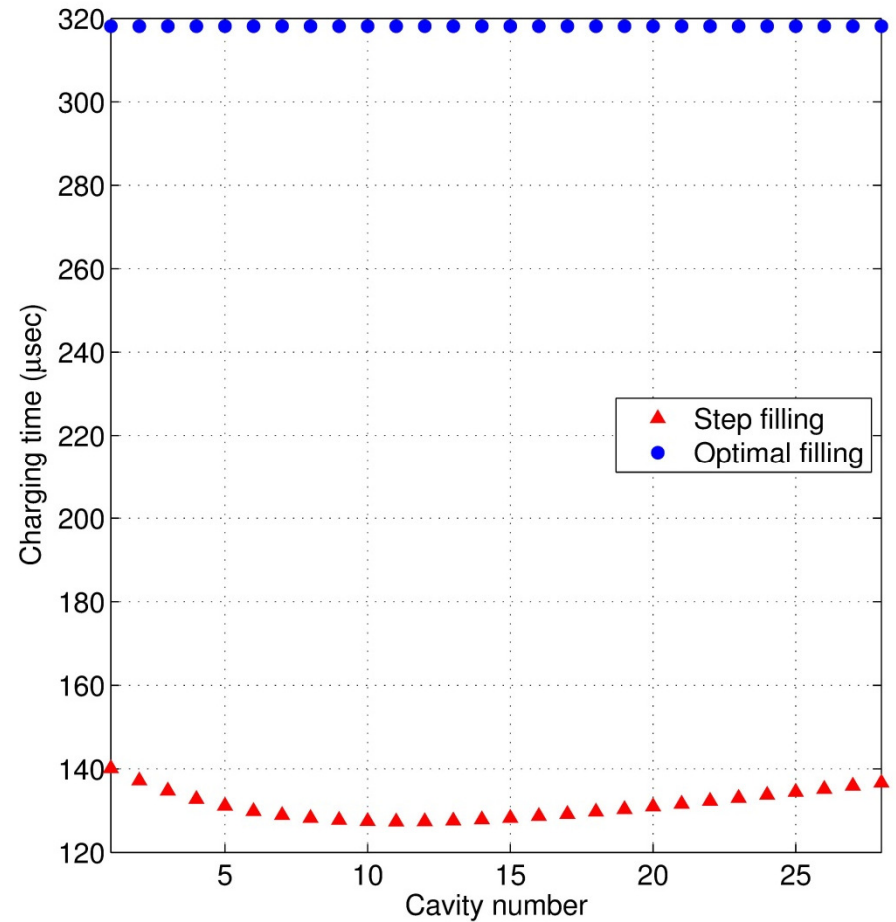


Variation Along Spoke LINAC

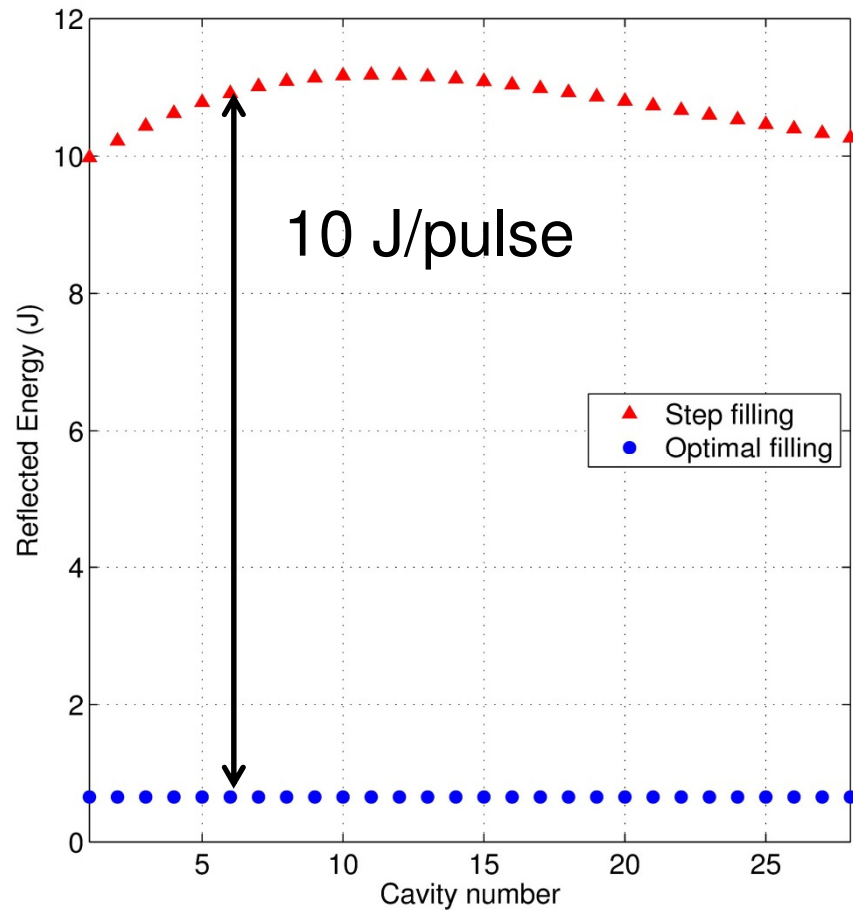
Beam injection time, $\hat{t}_i = 2t_F$



Peak power



Charging time

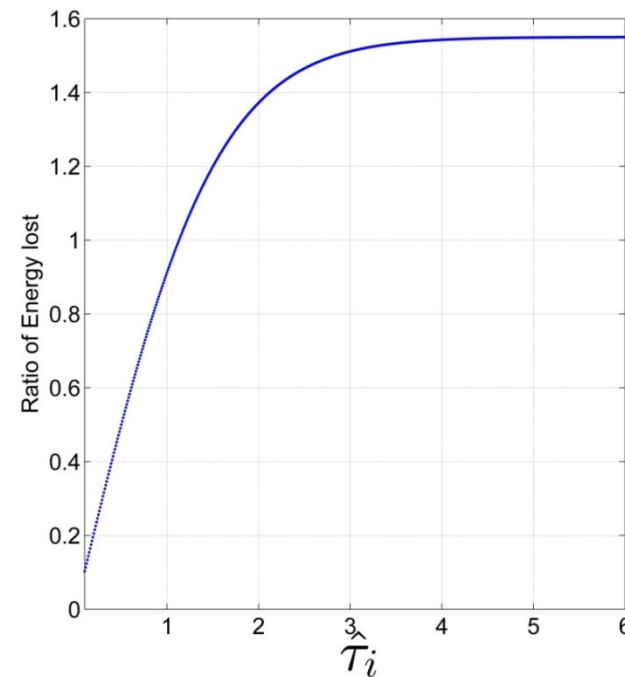


ESS operation: 14 Hz pulse rate
 140 J/sec saved
 per cavity

Assuming 8000 hours/year
 of operation 1.12 MWhrs
 saved per cavity
 2 SEK/kWhr => 2240 SEK

26 Spoke cavities, 20
 years of operation, =>
 1.16 MSEK

- Losses on cavity surface $P_d = \frac{\omega_0 U}{Q_0} = \frac{\omega_0 \frac{\mu_0}{2} \int_0^{\hat{t}_i} |B|^2 dV}{Q_0}$
- $|B|^2 \propto |V|^2$
- Ratio of energy loss

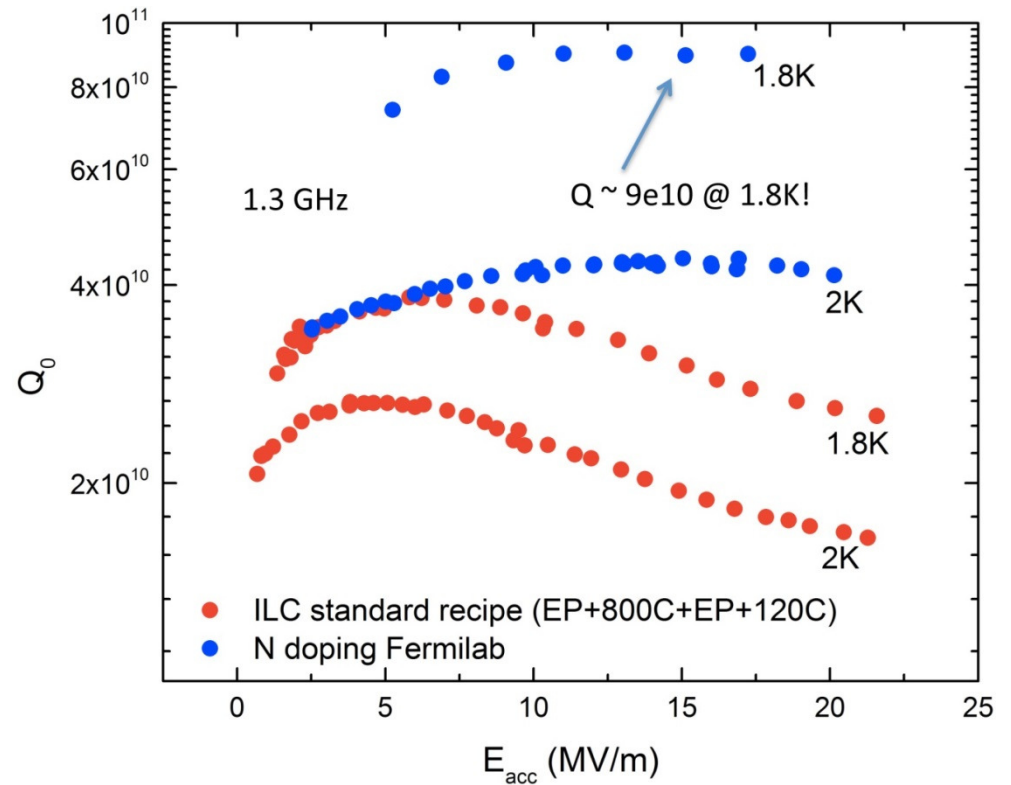


Q_0 \longrightarrow Intrinsic quality of the resonant structure

Cavity Quality factor



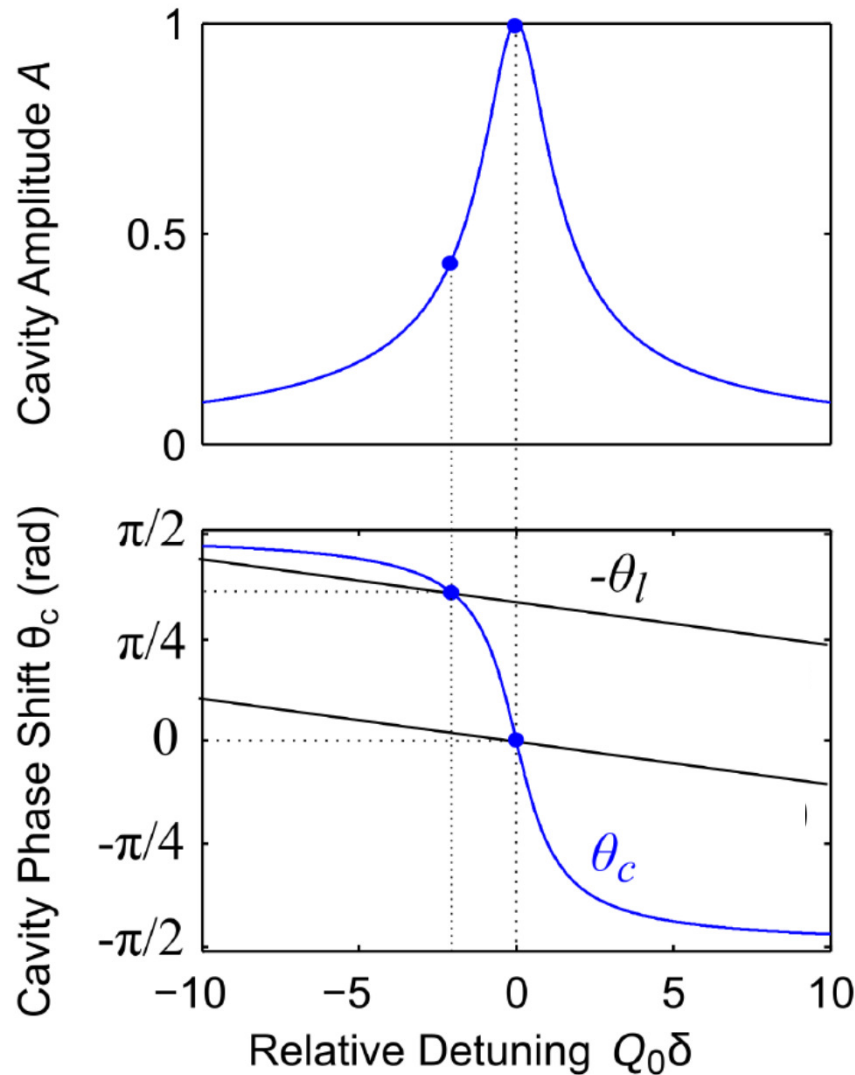
- To measure Quality factor of bare ESS superconducting spoke cavities
- Vertical tests in horizontal cryostat



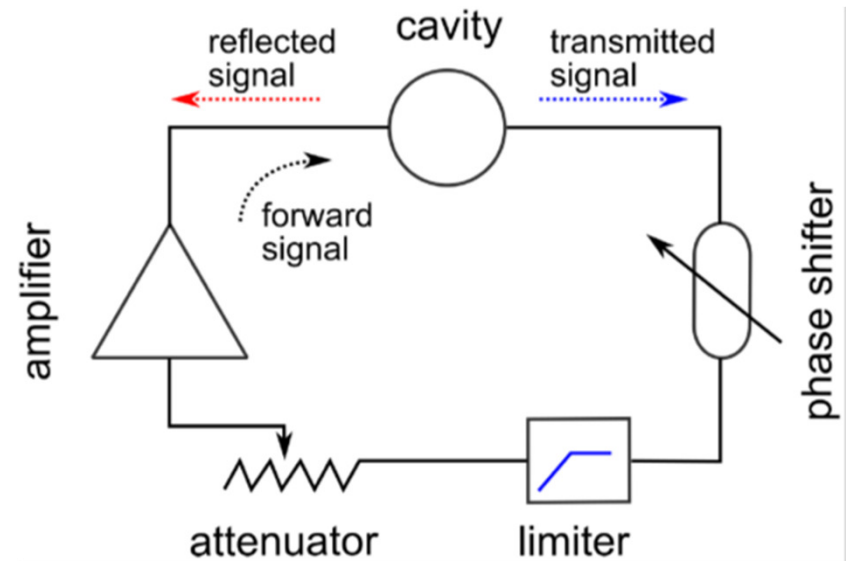
<http://newsline.linearcollider.org/2013/11/21/a-little-dirt-never-hurt/cavity-performance/>



$$\ddot{V} + \frac{\varepsilon_c}{Q_L} \dot{V} + \omega_c^2 V = 2\omega_c(R/Q)\dot{I}_i \quad Q_L = (Q_0^{-1} + Q_{ext}^{-1})^{-1}$$

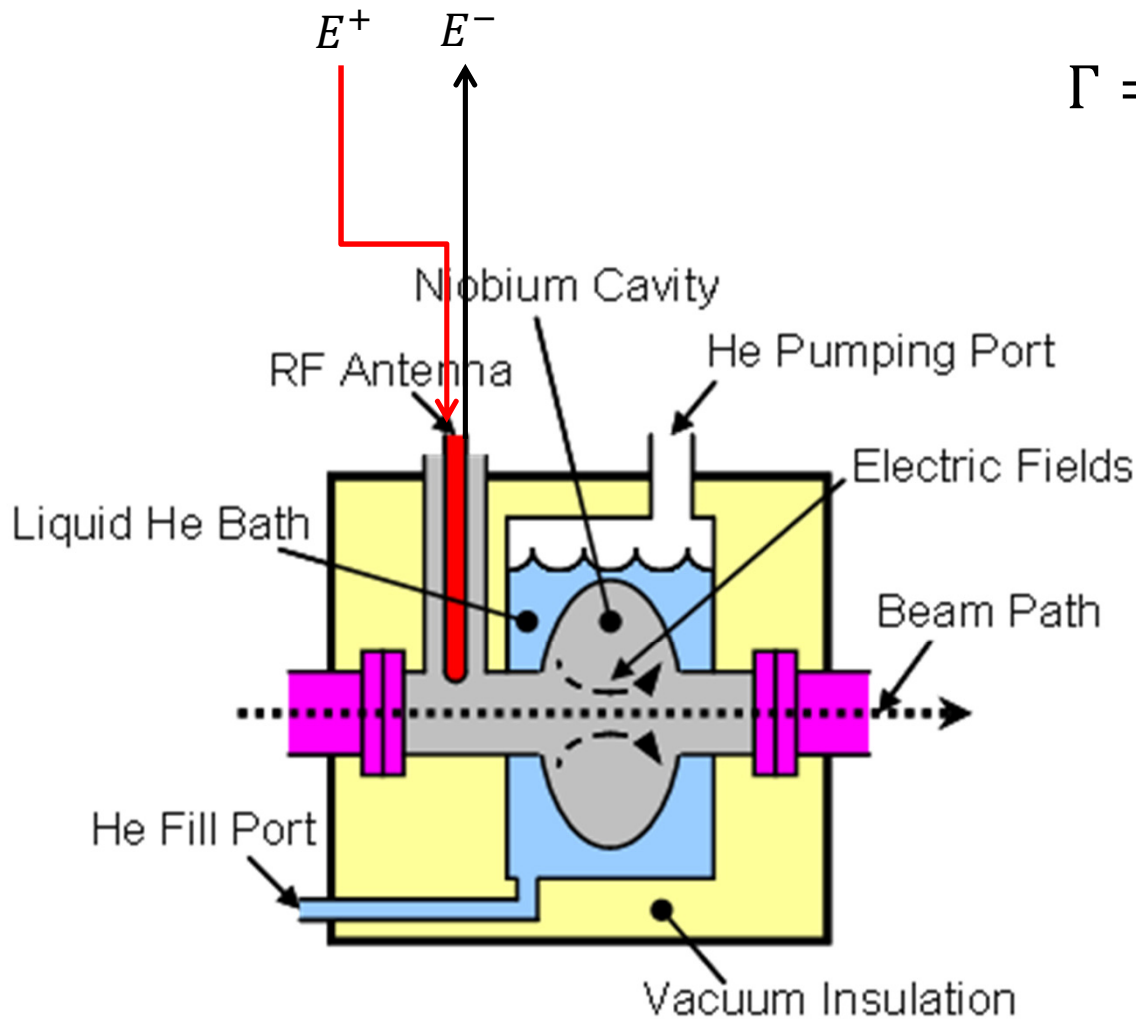


Self-excited loop



$$\theta_c(\omega) + \theta_l(\omega) = 2\pi n$$

Reflection coefficient



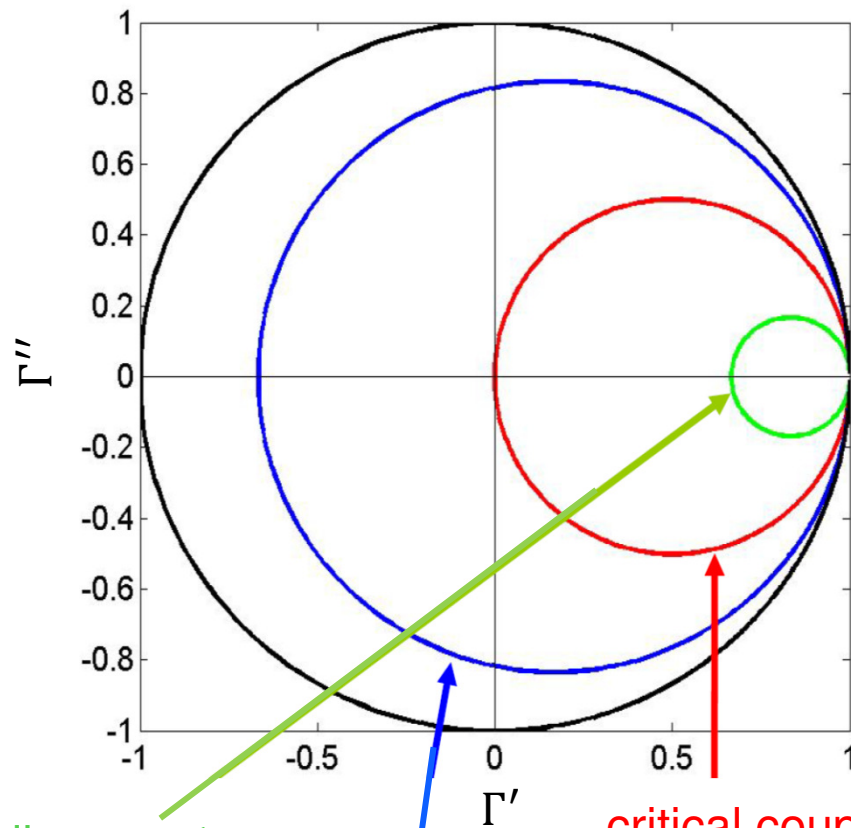
$$\Gamma = \frac{E^-}{E^+} = \frac{\kappa - 1 + iQ_0\delta}{\kappa + 1 - iQ_0\delta}$$

$$\delta = \frac{Q_{ext} + Q_0}{Q_{ext}Q_0} \tan \theta_c$$

Reflection coefficient



$$\left(\Gamma' + \frac{1}{1 + \kappa}\right)^2 + \Gamma''^2 = \left(\frac{\kappa}{1 + \kappa}\right)^2$$



under coupling $\kappa < 1$

over coupling $\kappa > 1$

critical coupling $\kappa = 1$

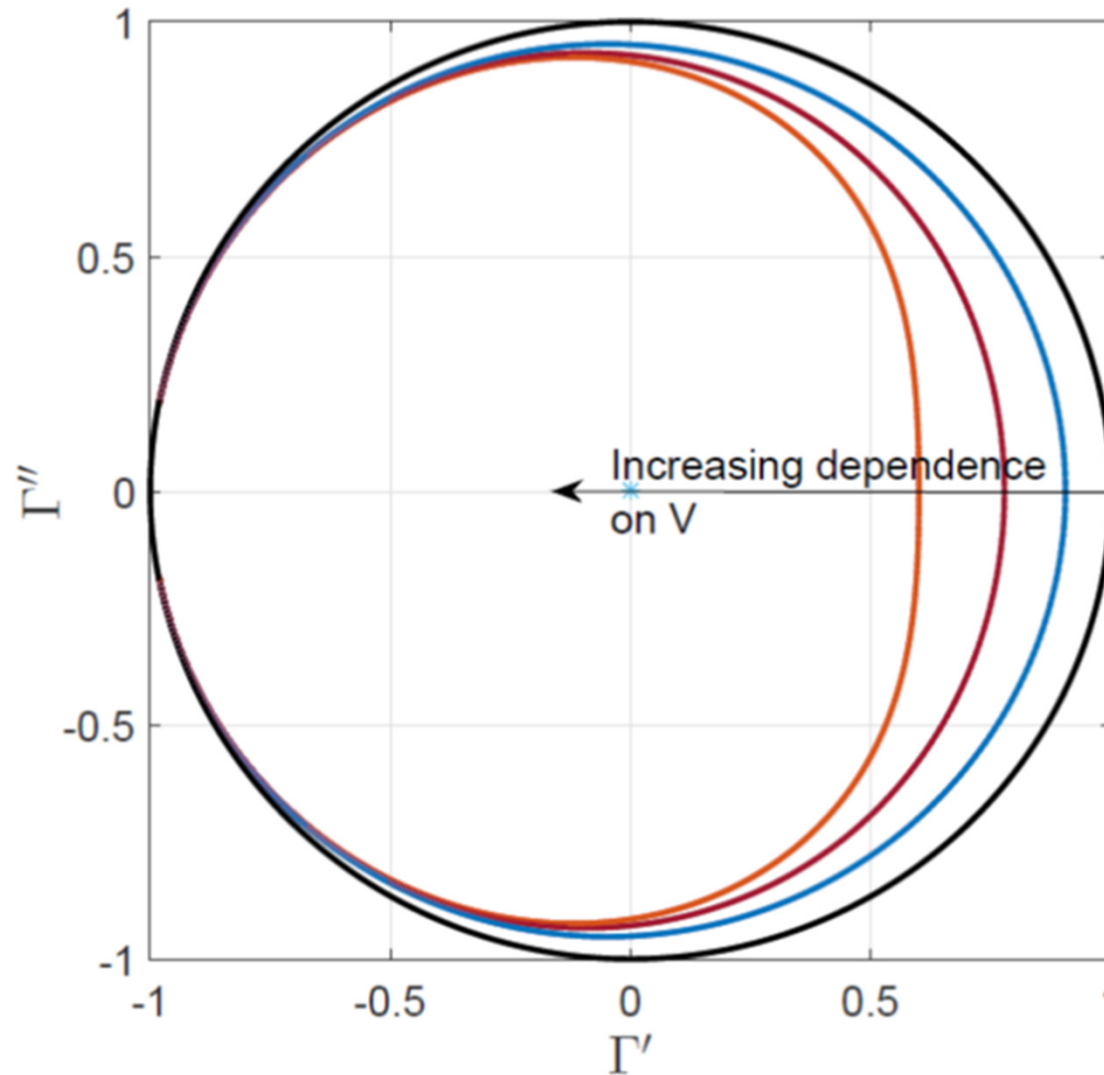
$$\kappa = \frac{Q_0}{Q_{ext}} = \frac{1}{\frac{1}{r} - 1}$$

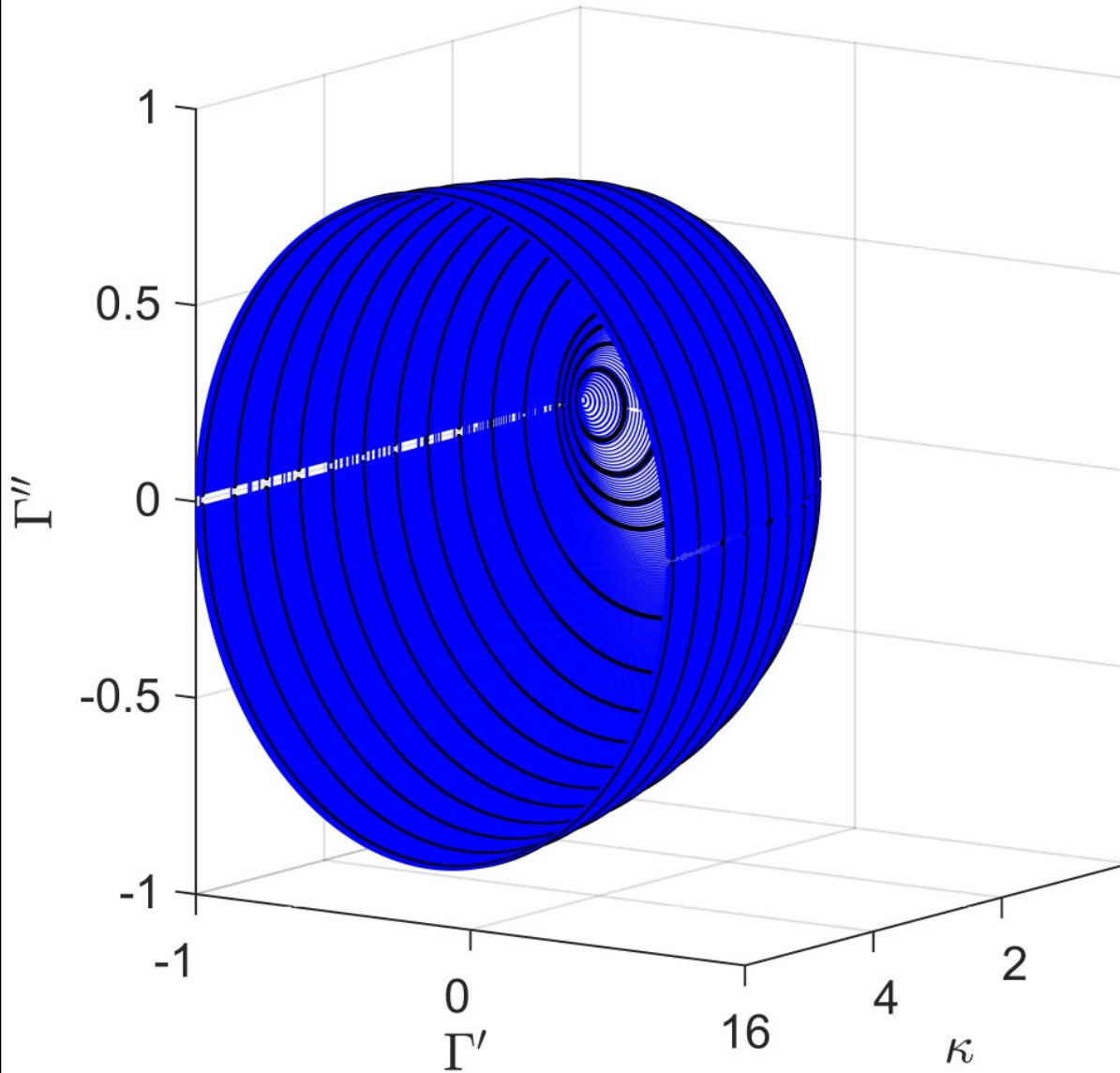
Superconducting cavity



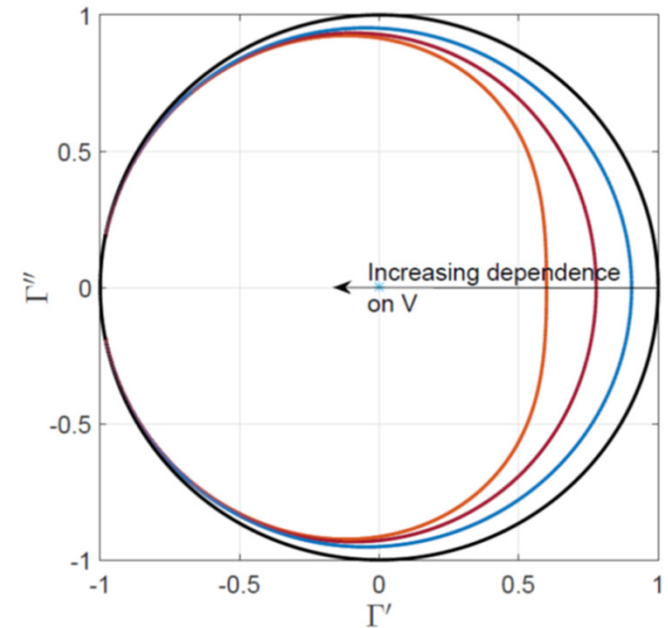
$$\left(\Gamma' + \frac{1}{1 + \kappa}\right)^2 + \Gamma''^2 = \left(\frac{\kappa}{1 + \kappa}\right)^2$$

$$\kappa = \frac{Q_0(V)}{Q_{ext}}$$

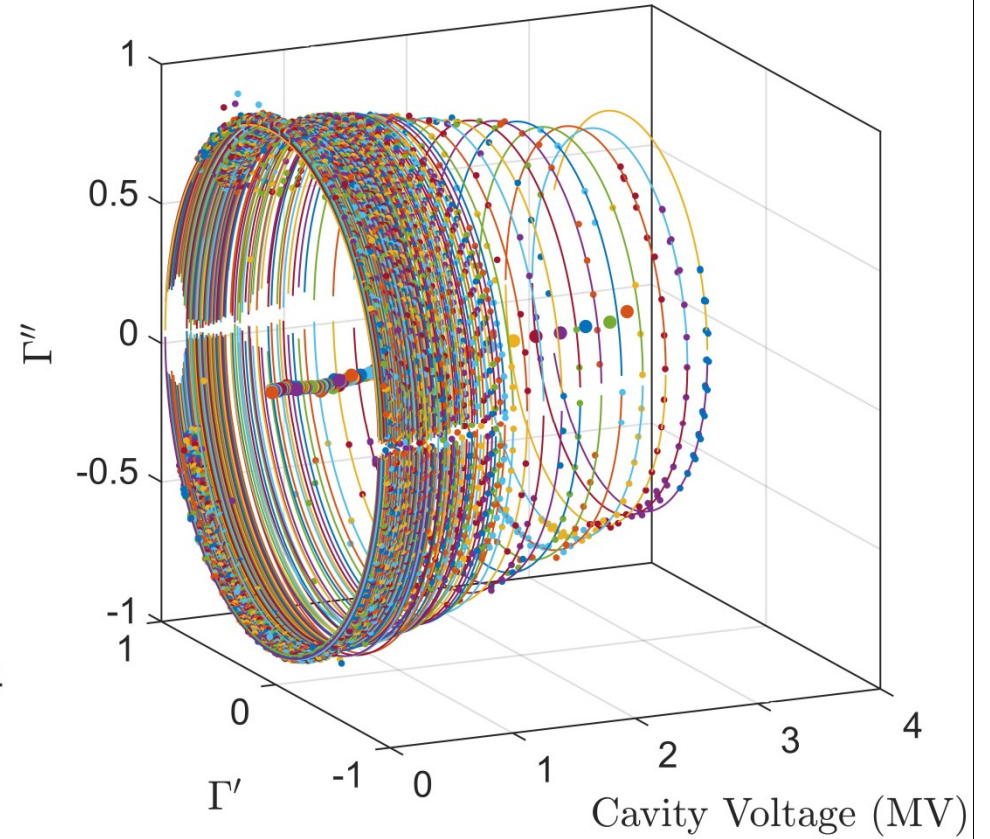
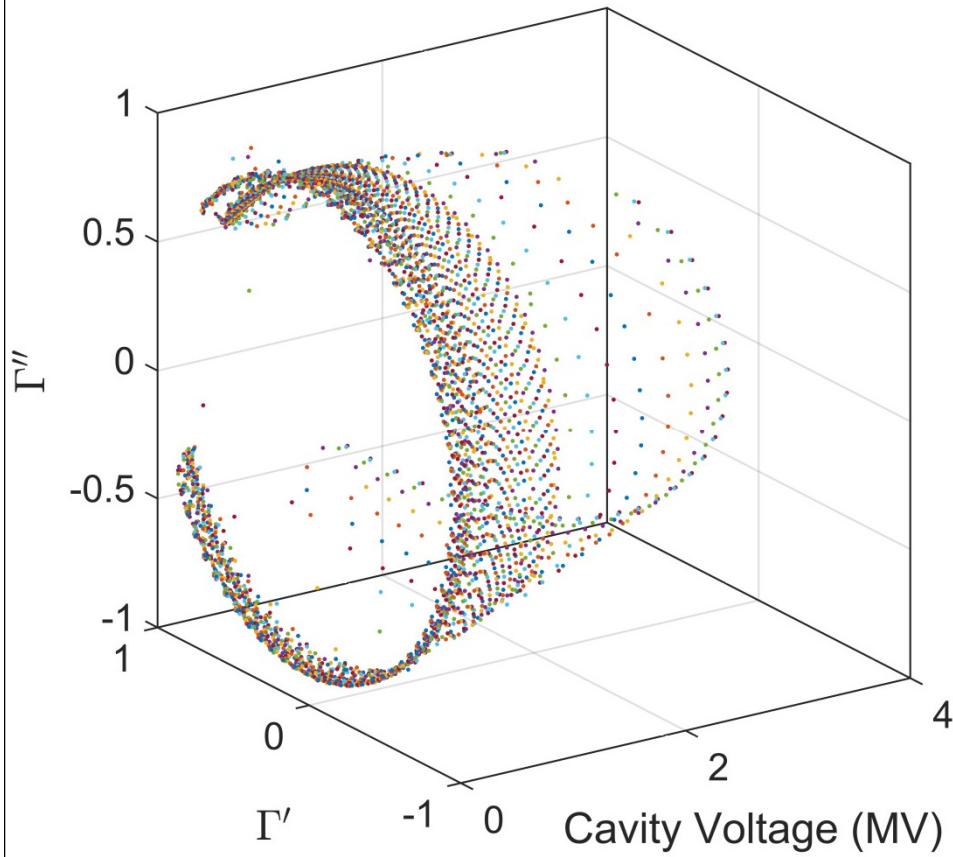




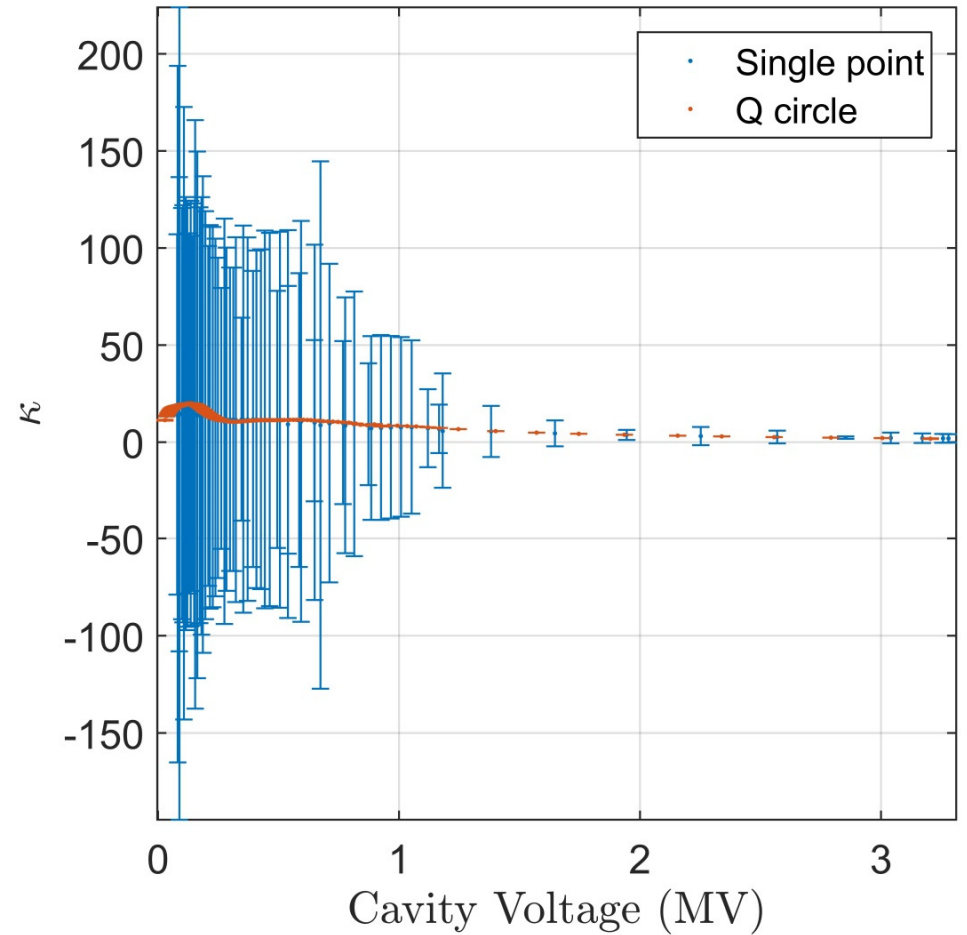
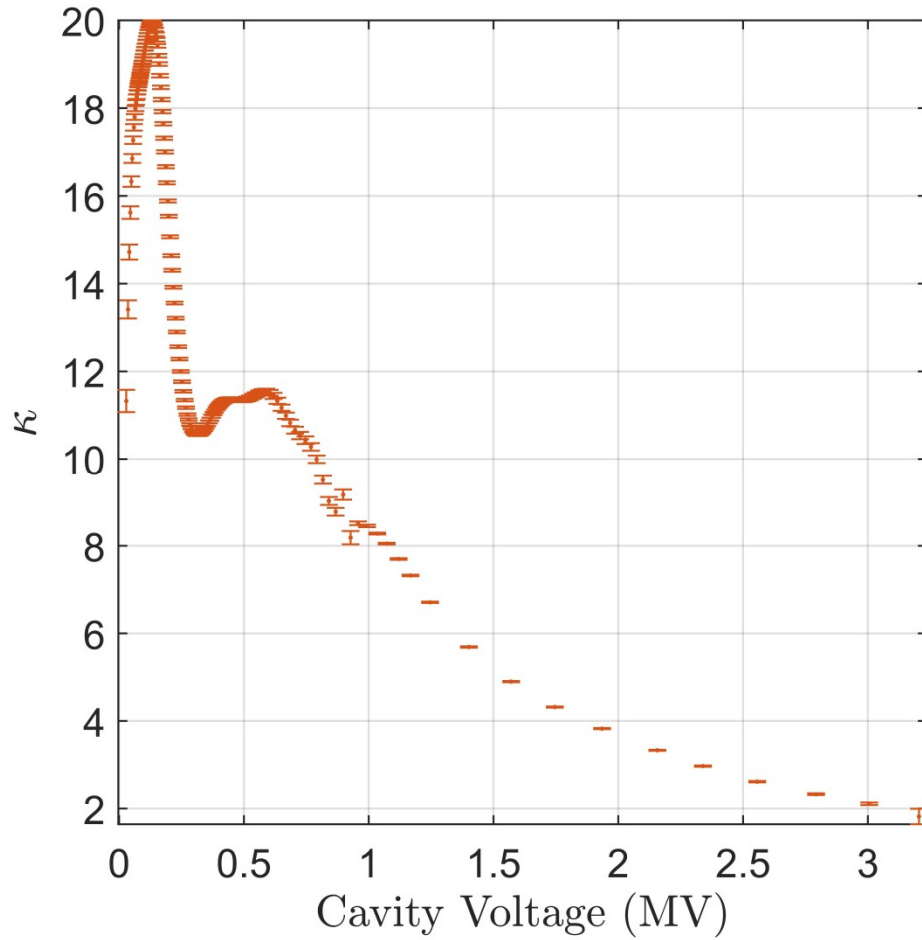
$$\left(\Gamma' + \frac{1}{1 + \kappa}\right)^2 + \Gamma''^2 = \left(\frac{\kappa}{1 + \kappa}\right)^2$$

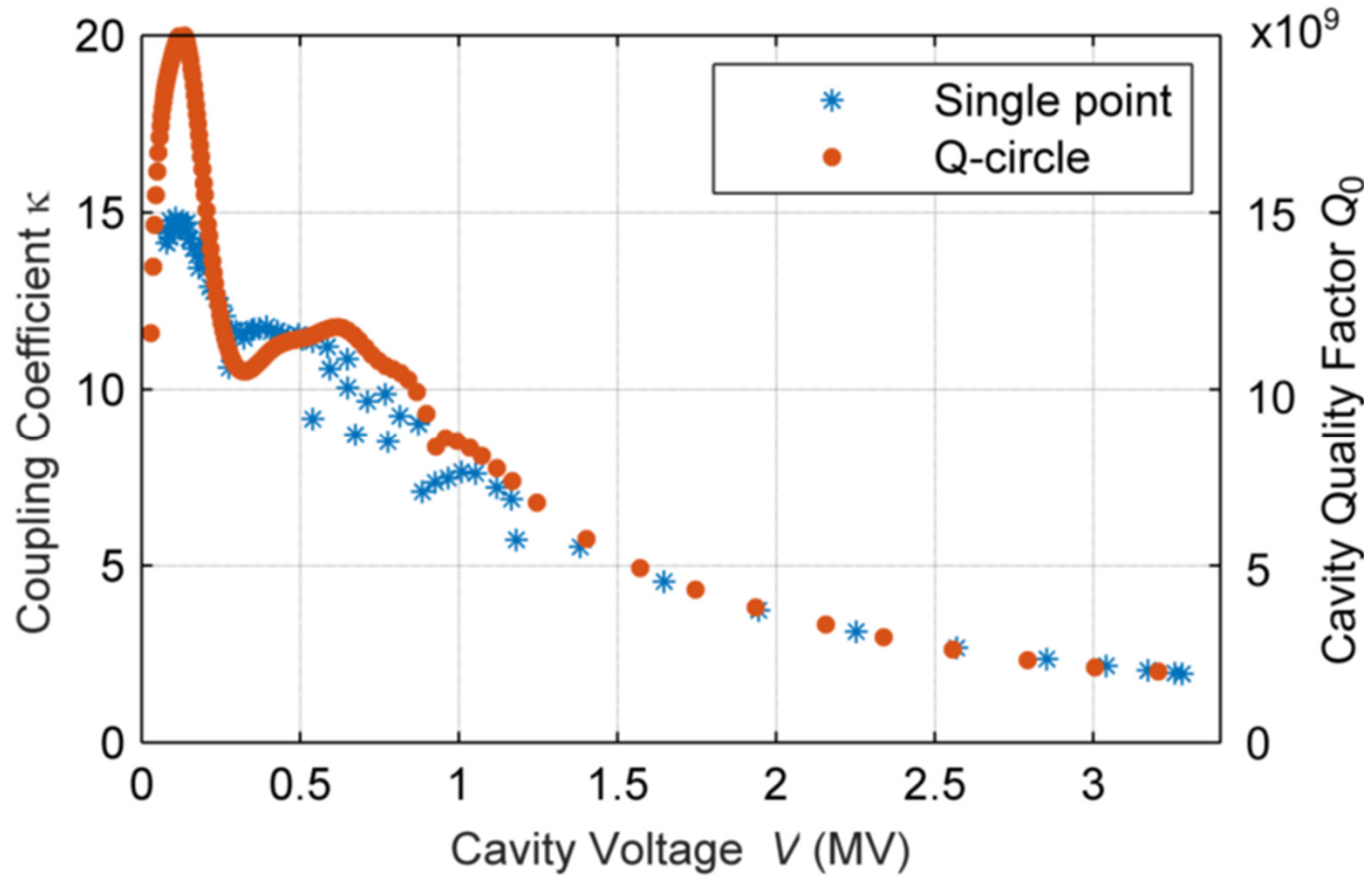


Q-surface



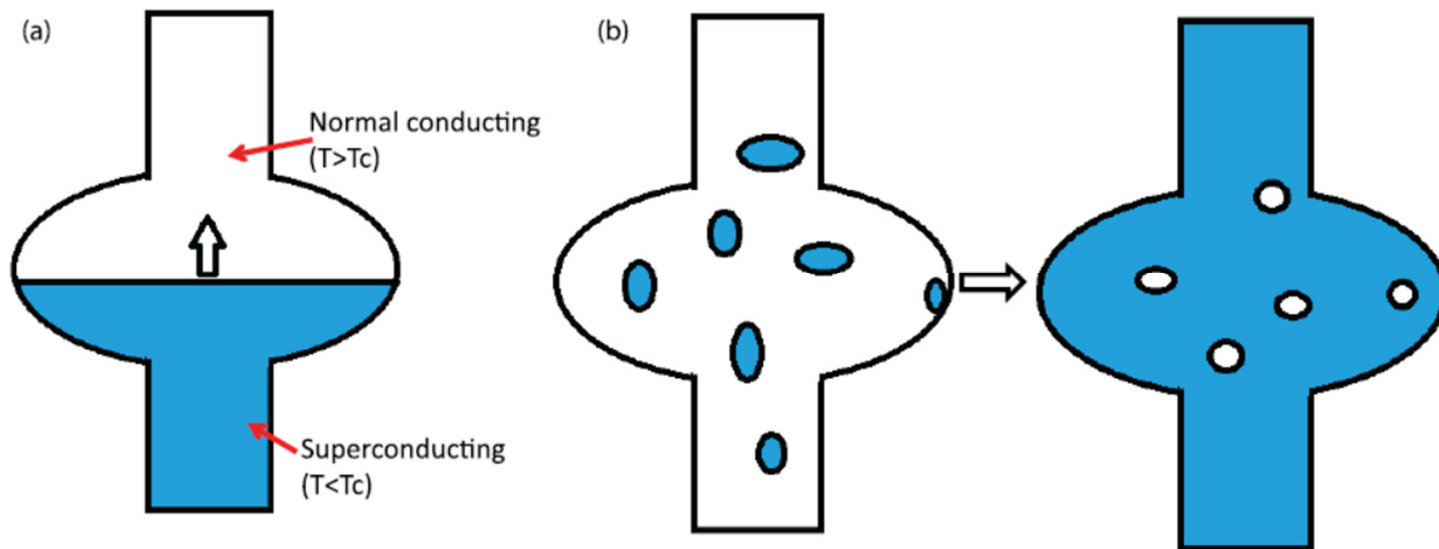
Double-spoke cavity



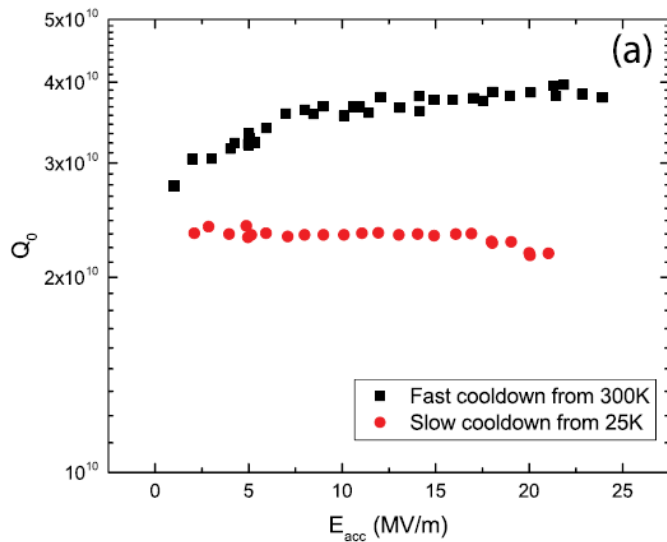
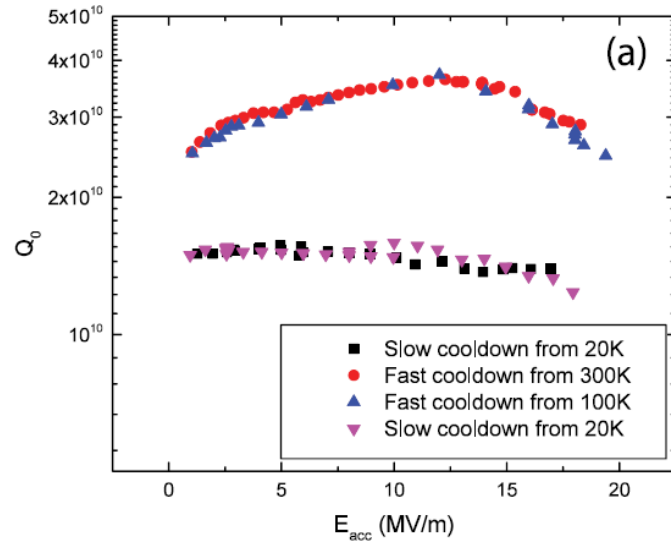


Residual resistance depends on trapped magnetic field

- Helmholtz Zentrum Berlin (HZB): magnetic field are generated by thermal currents.
- HZB & Cornell: Slow cooling to reduce thermal currents.
- Fermilab: Magnetic field (ambient) can be expelled by large temperature gradients creating a quick propagating super-conducting phase front.



Effect of cooling rate on Q_0



Ultra-high quality factors in superconducting niobium cavities in ambient magnetic fields up to 190 mG

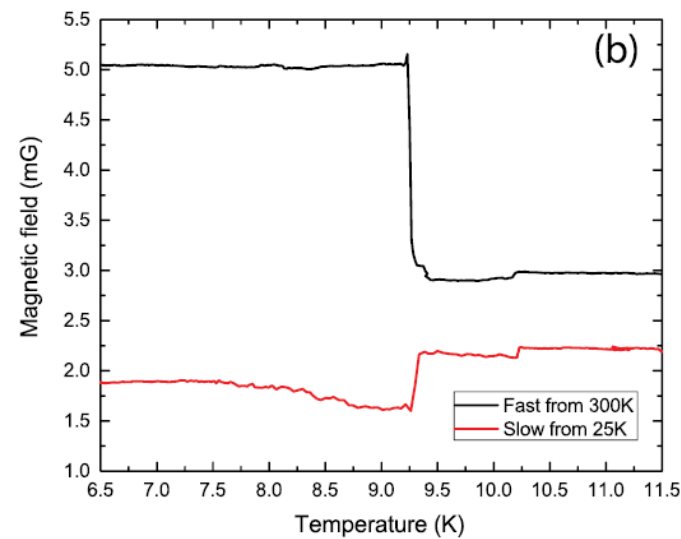
A. Romanenko,^{a)} A. Grassellino, A. C. Crawford, D. A. Sergatskov, and O. Melnychuk
Fermi National Accelerator Laboratory, Batavia, Illinois 60510, USA

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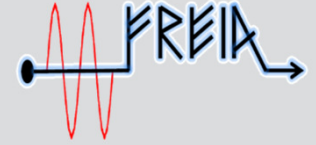
JOURNAL OF APPLIED PHYSICS **115**, 184903 (2014)

Dependence of the residual surface resistance of superconducting radio frequency cavities on the cooling dynamics around T_c

A. Romanenko,^{a)} A. Grassellino,^{b)} O. Melnychuk, and D. A. Sergatskov
Fermi National Accelerator Laboratory, Batavia, Illinois 60510, USA



Ginzburg-Landau Equations



$$\frac{1}{D} \left(\frac{\partial}{\partial t} + i2e\phi \right) \psi = - \left(\frac{\nabla}{i} - 2e\mathbf{A} \right)^2 \psi - \frac{1}{\xi(T)^2} (|\psi|^2 - 1) \psi,$$

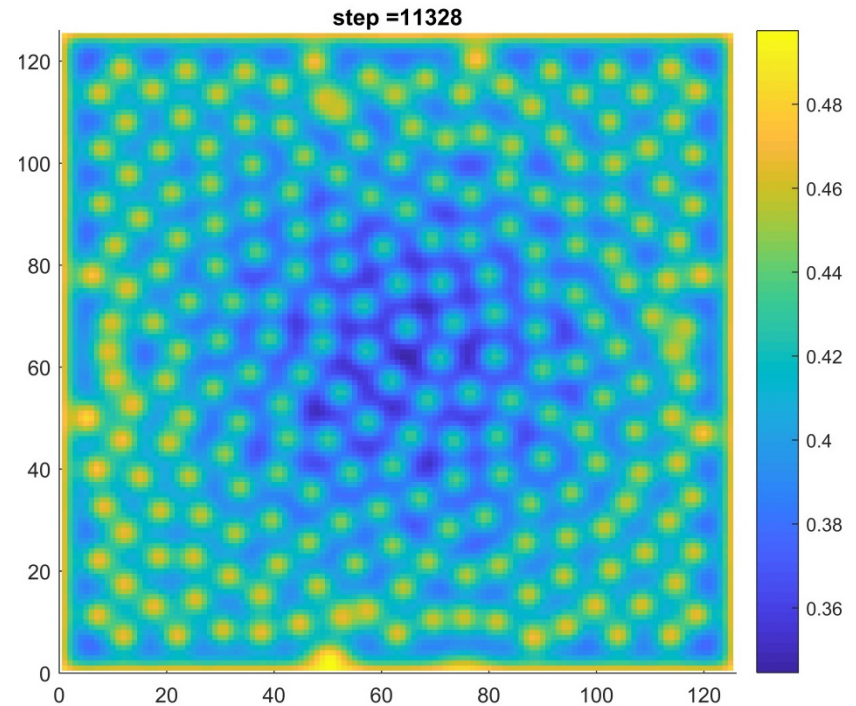
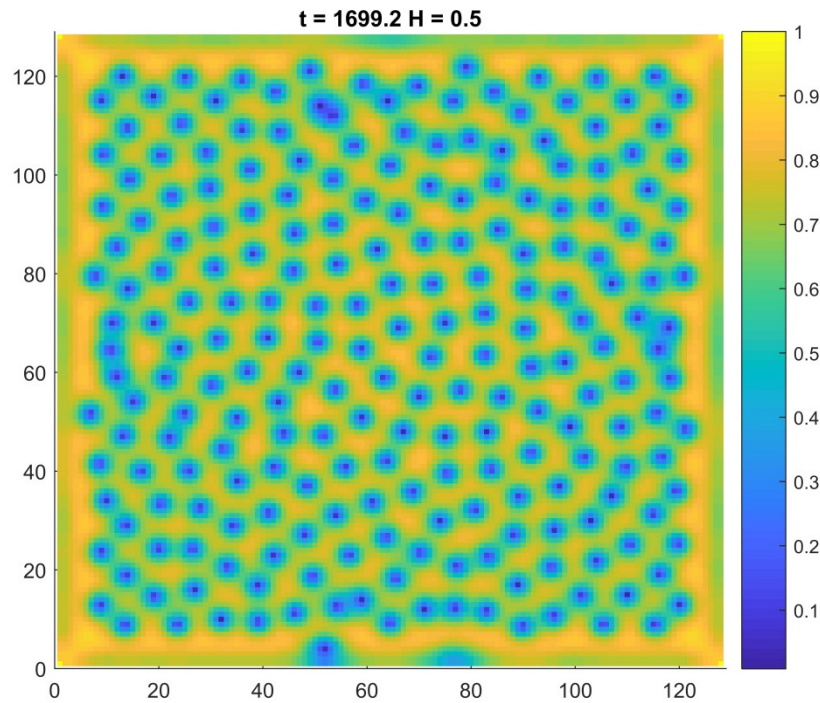
$$\mathbf{J} = \sigma \left(-\nabla\phi - \frac{\partial\mathbf{A}}{\partial t} \right) + \frac{1}{8\pi e\lambda(T)^2} \text{Real} \left[\psi^* \left(\frac{\nabla}{i} - 2e\mathbf{A} \right) \psi \right].$$

Journal of Computational Physics **179**, 127–139 (2002)
doi:10.1006/jcph.2002.7047

A Fast Semi-Implicit Finite-Difference Method for the TDGL Equations

T. Winiecki and C. S. Adams

Department of Physics, University of Durham, Rochester Building, South Road, Durham,
DH1 3LE, United Kingdom





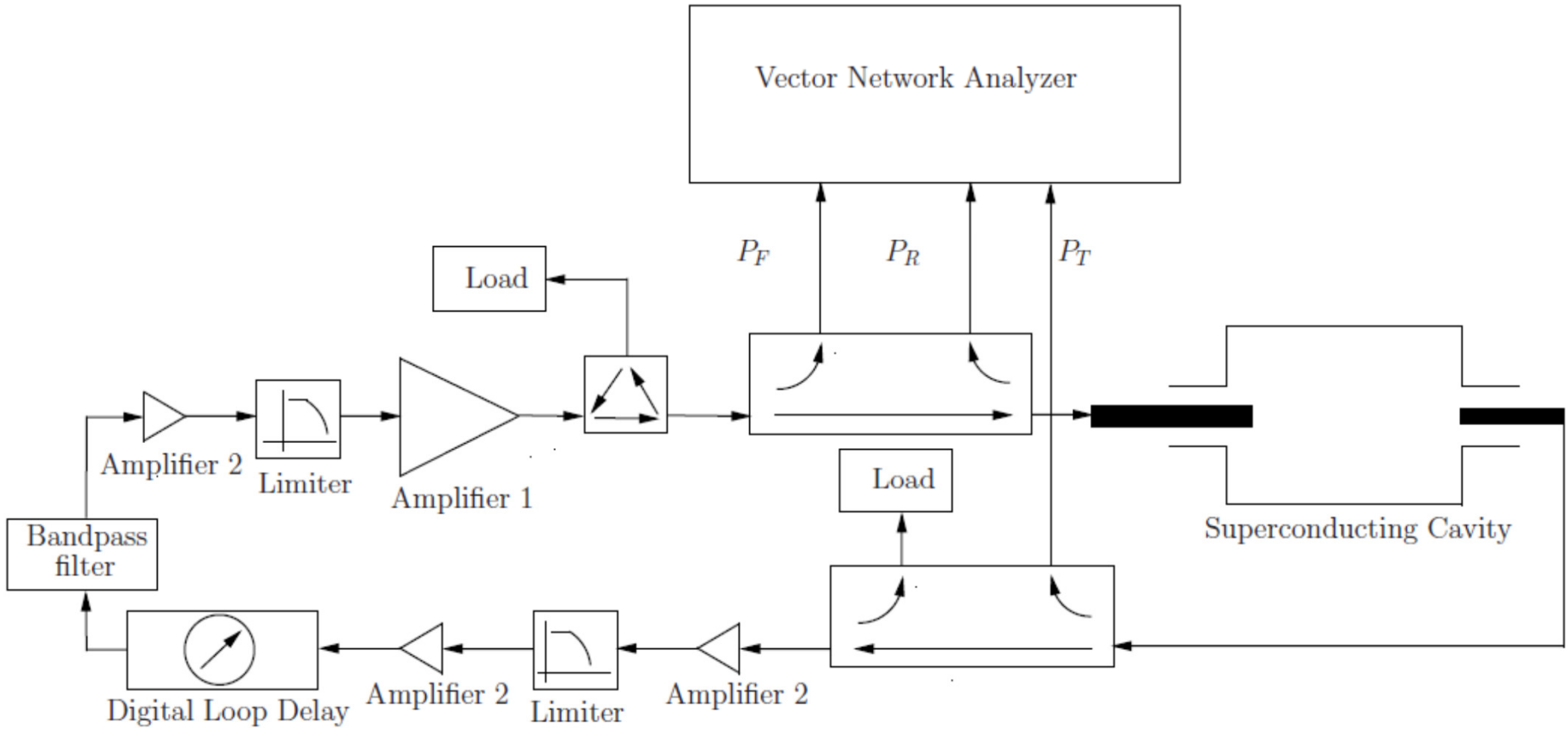
Conclusion



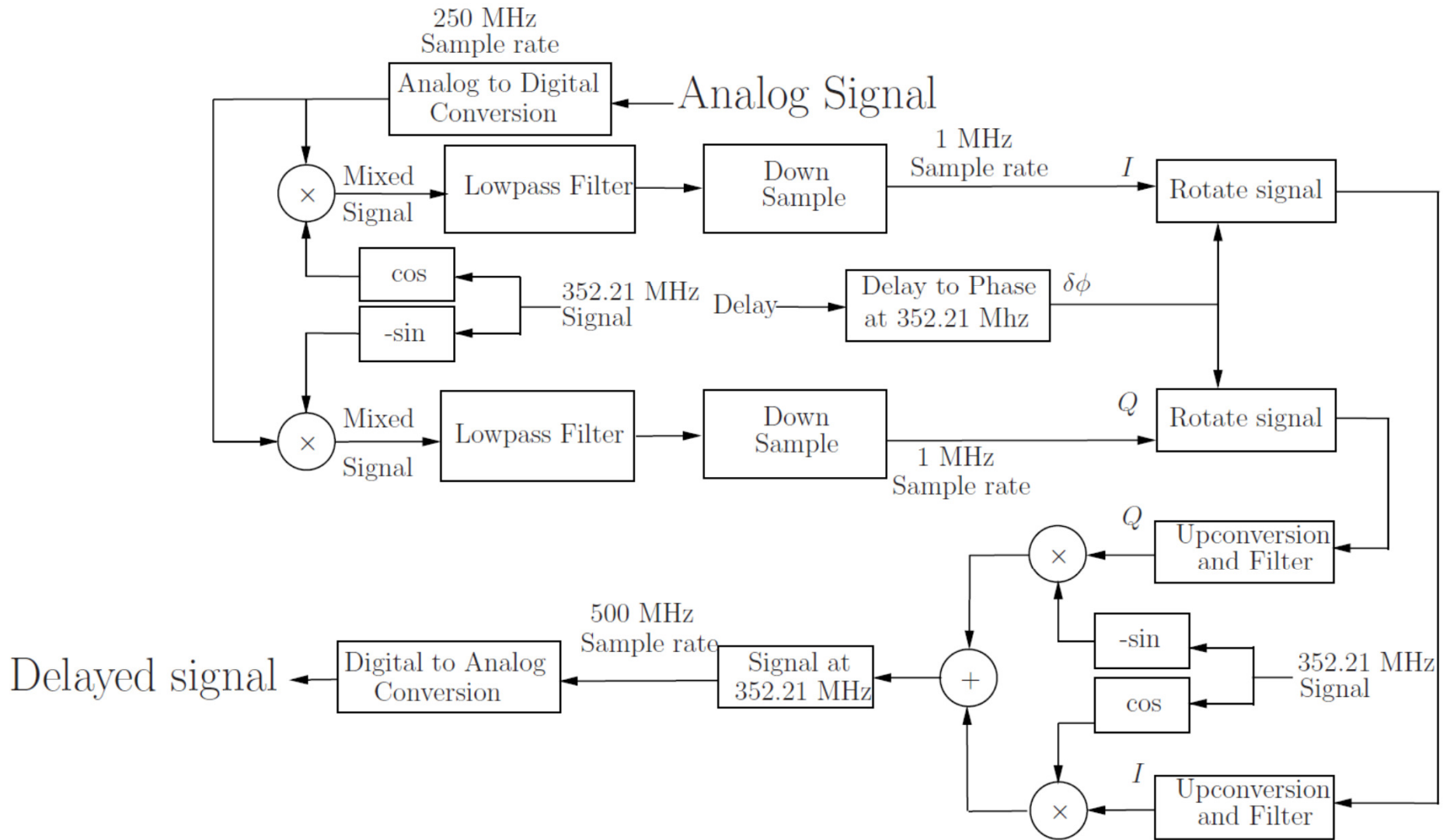
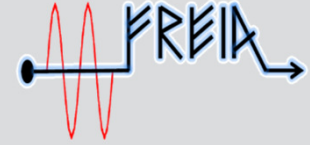
- Reflected energy and thus waste can be reduced by proposed filling profile.
- But physical factors provide constraints which require increased investigation to better understand the super-conducting cavity.
- The proposed Q_0 measurement technique provides a means of accurately characterising the gradient dependent character of the super-conducting cavities.
- The rate of cooling has been found to influence cavity Q_0 and the G-L equations provide a means of theoretically explaining experimental observations.



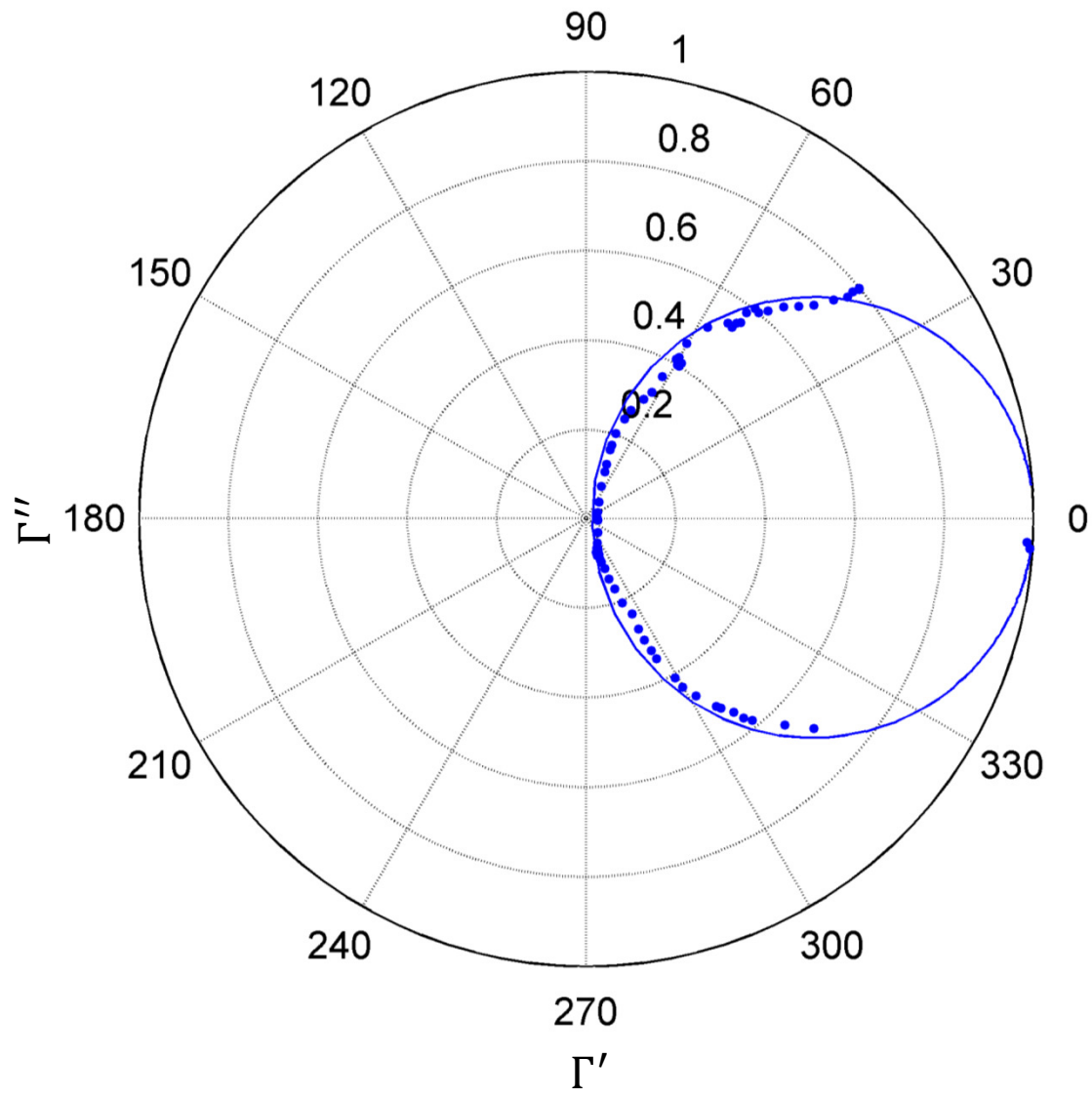
Thank You

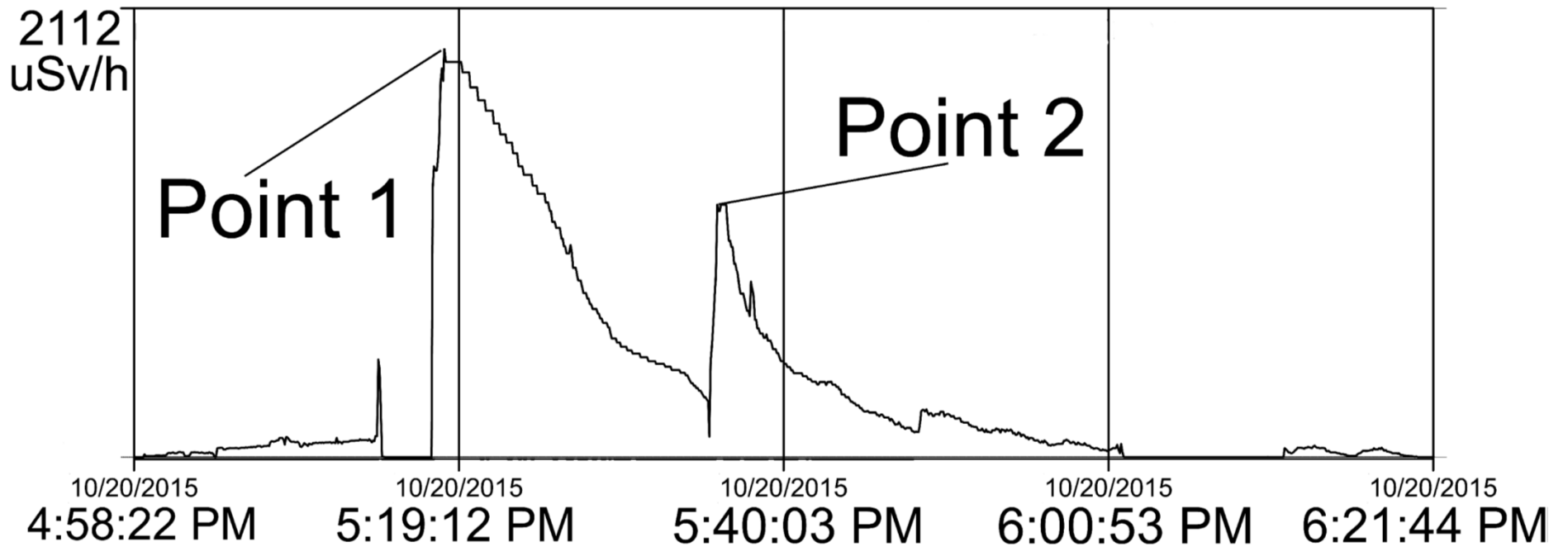


Digital loop delay



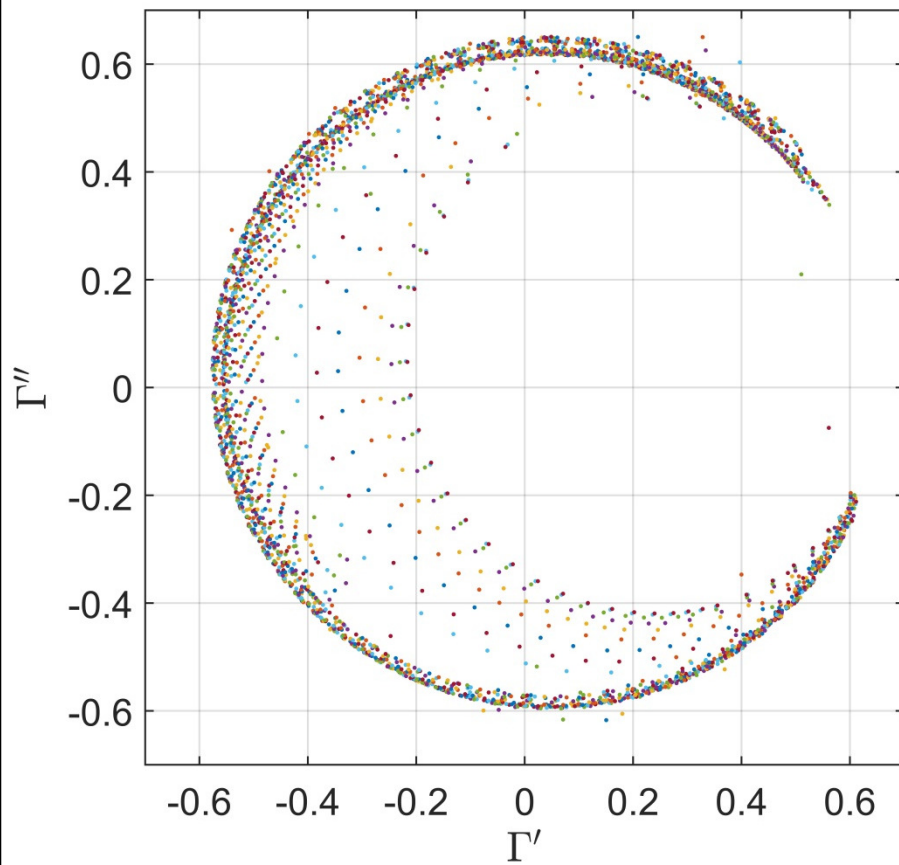
Normal conducting cavity







Before cable compensation



After cable compensation

